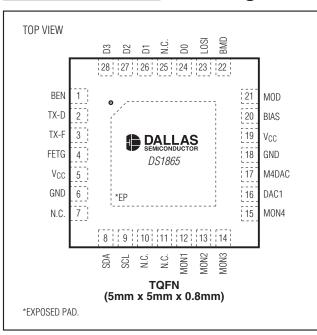
DALLAS MICONDUCTOR PON Triplexer Control and Monitoring Circuit

General Description

The DS1865 controls and monitors all the burst-mode transmitter and video receiver biasing functions for a passive optical network (PON) triplexer. It has an APC loop with tracking-error compensation that provides the reference for the laser driver bias current and a temperature-indexed lookup table (LUT) that controls the modulation current. It continually monitors for high output current, high bias current, and low and high transmit power with its internal fast comparators to ensure that laser shutdown for eye safety requirements are met without adding external components. Six ADC channels monitor V_{CC}, internal temperature, and four external monitor inputs (MON1–MON4) that can be used to meet transmitter and video receive signal monitoring requirements. Two digital-to-analog converter (DAC) outputs are available for biasing the video receiver channel, and five digital I/O pins are present to allow additional monitoring and configuration.

Applications

Optical Triplexers with GEPON, BPON, or GPON Transceiver



Pin Configuration

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Features

- Meets GEPON, BPON, and GPON Timing Requirements for Burst-Mode Transmitters
- Bias Current Control Provided by APC Loop with Tracking-Error Compensation
- Modulation Current is Controlled by a Temperature-Indexed Lookup Table
- Laser Power Leveling from -6dB to +0dB
- Two 8-Bit Analog Outputs, One is Controlled by MON4 Voltage for Video Amplifier Gain Control
- Internal Direct-to-Digital Temperature Sensor
- Six Analog Monitor Channels: Temperature, V_{CC}, MON1, MON2, MON3, and MON4
- Five Digital I/O Pins for Additional Control and Monitoring Functions
- Comprehensive Fault Management System with Maskable Laser Shutdown Capability
- Two-Level Password Access to Protect Calibration Data
- 120 Bytes of Password 1 Protected Nonvolatile Memory
- 128 Bytes of Password 2 Protected Nonvolatile Memory in Main Device Address
- 128 Bytes of Nonvolatile Memory Located at A0h Slave Address
- I²C-Compatible Interface for Calibration and Monitoring
- ♦ Operating Voltage: 2.85V to 3.9V
- ♦ Operating Temperature Range: -40°C to +95°C
- Packaging: 28-Pin Lead-Free TQFN (5mm x 5mm x 0.8mm)

Ordering Information

PART	TEMP RANGE	PIN-PACKAGE
DS1865T+	-40°C to +95°C	28 TQFN-EP*
DS1865T+T&R	-40°C to +95°C	28 TQFN-EP*

+Denotes a lead(Pb)-free/RoHS-compliant package. *EP = Exposed pad.

T&R = Tape and reel.

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For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

DS1865

ABSOLUTE MAXIMUM RATINGS

Voltage Range on MON1–MON4, BEN, BMD, and TX-D Pins Relative to Ground-0.5V to (V_{CC} + 0.5V) (subject to not exceeding +6V) Voltage Range on V_{CC}, SDA, SCL, D0–D3, and TX-F Pins Relative to Ground-0.5V to +6V

Operating Temperature Range	40°C to +95°C
Programming Temperature Range	e0°C to +70°C
Storage Temperature Range	55°C to +125°C
Soldering Temperature	See J-STD-020 Specification

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

 $(T_A = -40^{\circ}C \text{ to } +95^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP MAX	UNITS
Supply Voltage	Vcc	(Note 1)	+2.85	+3.9	V
High-Level Input Voltage (SDA, SCL, BEN)	VIH:1		0.7 x Vcc	V _{CC} + 0.3	V
Low-Level Input Voltage (SDA, SCL, BEN)	VIL:1		-0.3	0.3 x Vcc	V
High-Level Input Voltage (TX-D, LOSI, D0, D1, D2, D3)	V _{IH:2}		2.0	V _{CC} + 0.3	V
Low-Level Input Voltage (TX-D, LOSI, D0, D1, D2, D3)	VIL:2		-0.3	0.8	V

DC ELECTRICAL CHARACTERISTICS

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	МАХ	UNITS
Supply Current	ICC	(Notes 1, 2)		5	10	mA
Output Leakage (SDA, TX-F, D0, D1, D2, D3)	ILO				1	μA
Low-Level Output Voltage	Vol	$I_{OL} = 4mA$			0.4	V
(SDA, TX-F, FETG, D0, D1, D2, D3)	VOL	$I_{OL} = 6mA$			0.6	v
High-Level Output Voltage (FETG)	V _{OH}	I _{OH} = 4mA	V _{CC} - 0.4			V
FETG Before Recall		(Note 3)		10	100	nA
Input-Leakage Current (SCL, BEN, TX-D, LOSI)	ILI				1	μA
Digital Power-On Reset	POD		1.0		2.2	V
Analog Power-On Reset	POA		2.1		2.75	V

ELECTRICAL CHARACTERISTICS (DAC1 and M4DAC)

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
DAC Output Range			0		2.5	V
DAC Output Resolution				8		Bits
DAC Output Integral Nonlinearity			-2		+2	LSB
DAC Output Differential Nonlinearity			-1		+1	LSB
DAC Error		$T_A = +25^{\circ}C$	-1.25		+1.25	LSB
DAC Temperature Drift			-2		+2	% FS
DAC Offset		$V_{CC} = 2.85V$ to 3.6V	-20		+20	μV
Maximum Load			-500		+500	μA
Maximum Load Capacitance					250	pF

ANALOG INPUT CHARACTERISTICS (BMD, TXP-HI, TXP-LO, HBIAS)

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
BMD, TXP-HI, TXP-LO Full-Scale Voltage	VAPC	(Note 4)		2.5		V
HBIAS Full-Scale Voltage				1.25		mA
BMD Input Resistance			35	50	65	kΩ
Resolution		(Note 4)		8		Bits
Error		$T_{A} = +25^{\circ}C$ (Note 5)		±2		%FS
Integral Nonlinearity			-1		+1	LSB
Differential Nonlinearity			-1		+1	LSB
Temperature Drift			-2.5		+2.5	%FS

ANALOG OUTPUT CHARACTERISTICS

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
BIAS Current	IBIAS	(Note 1)		1.2		mA
IBIAS Shutdown Current	IBIAS:OFF			10	100	nA
Voltage at IBIAS			0.7	1.2	1.4	V
MOD Full-Scale Voltage	Vmod	(Note 6)		1.25		V
MOD Output Impedance		(Note 7)		3		kΩ
V _{MOD} Error		T _A = +25°C (Note 8)	-2.5		+2.5	%FS
V _{MOD} Integral Nonlinearity			-3		+3	LSB
V _{MOD} Differential Nonlinearity			-1		+1	LSB
V _{MOD} Temperature Drift			-2		+2	%FS

ANALOG VOLTAGE MONITORING

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARA	METER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
Input Resolution	l	ΔVMON			610		μV
Supply Resolution	on	ΔV_{CC}			1.6		mV
Input/Supply Ac (MON1, MON2, N	curacy 10N3, MON4, V _{CC})	Acc	At factory setting		0.25	0.5	% FS (full scale)
Update Rate for MON3, MON4 T		^t FRAME			30	45	ms
Input/Supply Of (MON1, MON2, N	fset 10N3, MON4, V _{CC})	V _{OS}	(Note 14)		0	5	LSB
Factory Setting	MON1, MON2, MON3, MON4				2.5		V
	V _{CC}				6.5536		1

DIGITAL THERMOMETER

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Thermometer Error	T _{ERR}	-40°C to +95°C			±3.0	°C

TIMING CHARACTERISTICS (CONTROL LOOP AND QUICK-TRIP)

(V_{CC} = +2.85V to +3.9V, T_A = -40°C to +95°C, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
First MD Sample Following BEN	t FIRST	(Note 9)				
Remaining Updates During BEN	UPDATE	(Note 9)				
BEN High Time	tBEN:HIGH		400			ns
BEN Low Time	tBEN:LOW		96			ns
Output-Enable Time Following POA	tinit		10			ms
BIAS and MOD Turn-Off Delay	tOFF				5	μs
BIAS and MOD Turn-On Delay	ton				5	μs
FETG Turn-On Delay	tFETG:ON				5	μs
FETG Turn-Off Delay	tFETG:OFF				5	μs
Binary Search Time	^t SEARCH	(Note 10)	5		13	BIAS Samples
ADC Round-Robin Time	t _{RR}				75	ms

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I²C AC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +2.85V \text{ to } +3.9V, T_A = -40^{\circ}C \text{ to } +95^{\circ}C, \text{ timing referenced to } V_{IL(MAX)} \text{ and } V_{IH(MIN)}.)$ (See Figure 9.)

PARAMETER	SYMBOL	CONDITIONS	MIN TY	P MAX	UNITS
SCL Clock Frequency	fscl	(Note 11)	0	400	kHz
Clock Pulse-Width Low	tLOW		1.3		μs
Clock Pulse-Width High	thigh		0.6		μs
Bus-Free Time Between STOP and START Condition	tBUF		1.3		μs
Start Hold Time	thd:Sta		0.6		μs
Start Setup Time	tsu:sta		0.6		μs
Data in Hold Time	thd:dat		0	0.9	μs
Data in Setup Time	tsu:dat		100		ns
Rise Time of Both SDA and SCL Signals	t _R	(Note 12)	20 + 0.1C _B	300	ns
Fall Time of Both SDA and SCL Signals	tF	(Note 12)	20 + 0.1C _B	300	ns
STOP Setup Time	tsu:sto		0.6		μs
Capacitive Load for Each Bus Line	CB	(Note 12)		400	рF
EEPROM Write Time	tw	(Note 13)		20	ms

NONVOLATILE MEMORY CHARACTERISTICS

 $(V_{CC} = +2.85V \text{ to } +3.9V)$

PARAMETER	SYMBOL	CONDITIONS	MIN	ТҮР	MAX	UNITS
EEPROM Write Cycles		At +70°C	50,000			

Note 1: All voltages are referenced to ground. Current into IC is positive, out of the IC is negative.

Note 2: Digital inputs are at rail. FETG is disconnected. SDA = SCL = V_{CC}. DAC1 and M4DAC are not loaded.

Note 3: See the *Safety Shutdown (FETG) Output* section for details.

Note 4: Eight ranges allow the full-scale range to change from 625mV to 2.5V.

Note 5: This specification applies to the expected full-scale value for the selected range. See the Comp Ranging byte for available full-scale ranges.

Note 6: Eight ranges allow the BMD full-scale range to change from 312.5mV to 1.25V.

Note 7: The output impedance of the DS1865 is proportional to its scale setting. For instance, if using the 1/2 scale, the output impedance would be approximately $1.56k\Omega$.

Note 8: This specification applies to the expected full-scale value for the selected range. See the Mod Ranging byte for available full-scale ranges.

Note 9: See the APC and Quick-Trip Shared Comparator Timing section for details.

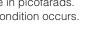
Note 10: Assuming an appropriate initial step is programmed that would cause the power to exceed the APC set point within four steps, the bias current will be 1% within the time specified by the binary search time. See the *Bias and MOD Output During Power-Up* section.

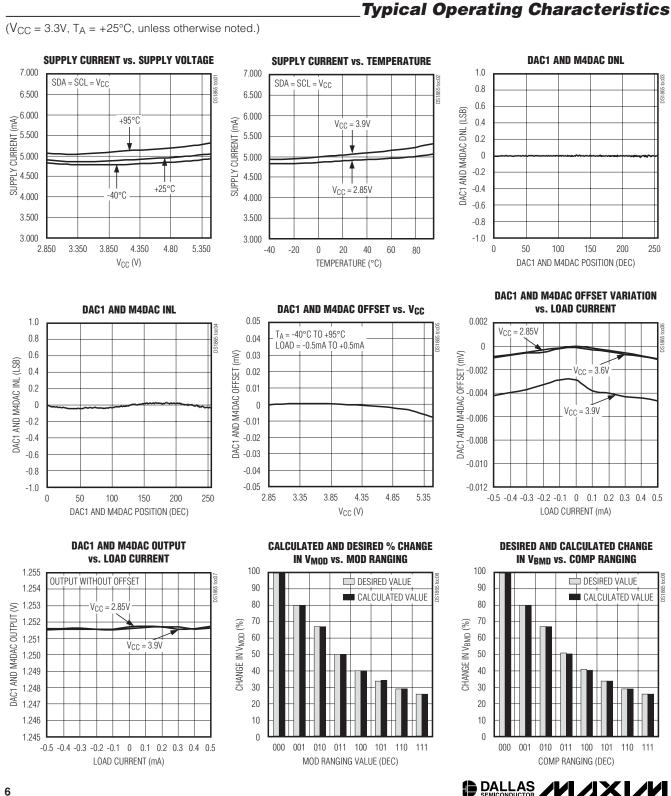
Note 11: I²C interface timing shown is for fast-mode (400kHz) operation. This device is also backward-compatible with the I²C standard mode.

Note 12: CB-total capacitance of one bus line in picofarads.

Note 13: EEPROM write begins after a STOP condition occurs.

Note 14: Guaranteed by design.





DS1865

Typical Operating Characteristics (continued)

USING FACTORY-PROGRAMMED

FULL-SCALE VALUE OF 2.5V

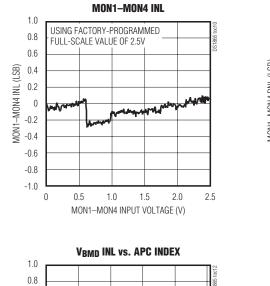
1.0

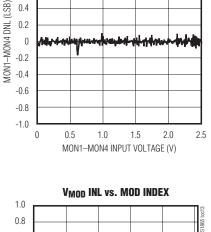
0.8

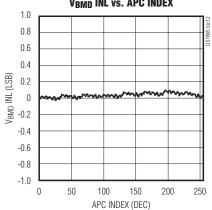
0.6

MON1-MON4 DNL

 $(V_{CC} = 3.3V, T_A = +25^{\circ}C, unless otherwise noted.)$







0.6 0.4 V_{MOD} INL (LSB) 0.2 0 -0.2 -0.4 -0.6 -0.8 -1.0 0 50 200 250 100 150 MOD INDEX (DEC)

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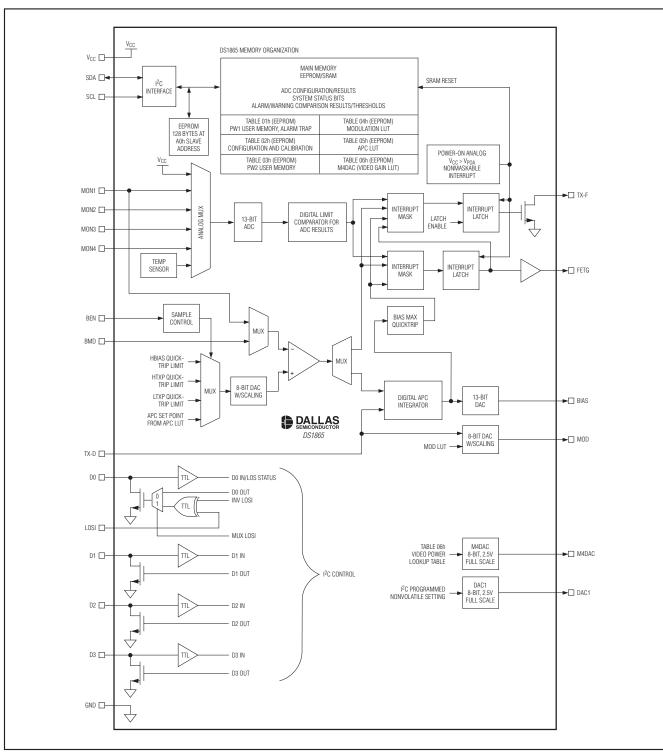
DS1865

_Pin Description

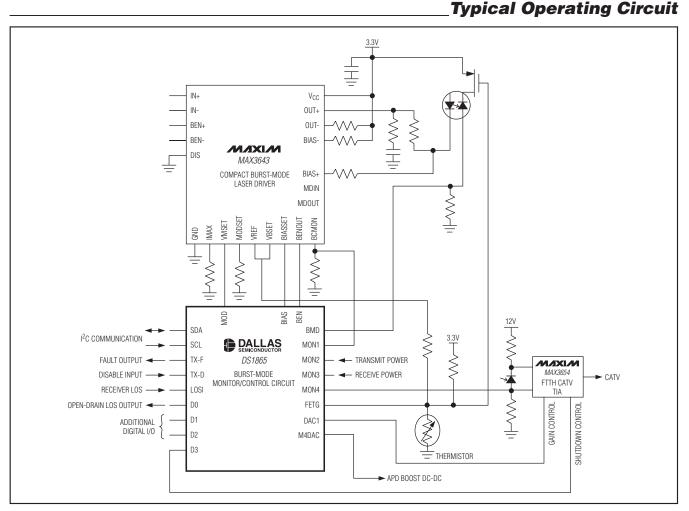
PIN	NAME	FUNCTION
1	BEN	Burst Enable Input. Triggers the sampling of the APC and quick-trip monitors.
2	TX-D	Transmit Disable Input. Disables BIAS and MOD outputs.
3	TX-F	Transmit Fault Output, Open Drain
4	FETG	Output to FET Gate. Signals an external n- or p-channel MOSFET to enable/disable the laser's current.
5, 19	V _{CC}	Supply Voltage
6, 18	GND	Ground
7, 10, 11, 25	N.C.	No Connection
8	SDA	I ² C Serial Data. Input/output for I ² C data.
9	SCL	I ² C Serial Clock. Input for I ² C clock.
12–15	MON1-MON4	External Monitor Input 1–4. The voltage at these pins are digitized by the internal analog-to-digital converter and can be read through the I ² C interface. Alarm and warning values can be assigned to interrupt the processor based on the ADC result.
16 17	DAC1 M4DAC	Digital-to-Analog Output DAC1 and M4DAC. Two 8-bit DAC outputs for generating analog voltages. Typically used to control the video photodiode bias. M4DAC is controlled by the input voltage on MON4 and Table 06h LUT.
20	BIAS	Bias Current Output. This current DAC generates the bias current reference for the MAX3643.
21	MOD	Modulation Output Voltage. This 8-bit voltage output has eight full-scale ranges from 1.25V to 0.3125V. This pin is connected to the MAX3643's VMSET input to control the modulation current.
22	BMD	Monitor Diode Input (Feedback Voltage, Transmit Power Monitor)
23	LOSI	Loss-of-Signal Input. This input is accessible in the status register through the I ² C interface.
24	D0	Digital I/O 0. This signal is either the open-drain output driver for LOSI, or can be controlled by the OUT0 bit (D0OUT). The logic level of this pin is indicated by the D0IN and LOS status bits.
26, 27, 28	D1, D2, D3	Digital I/O 1–3. These are bidirectional pins controlled by internally addressable bits. The outputs are open-drain.
_	EP	Exposed Pad. This contact should be connected to GND.

_Block Diagram

DS1865



DS1865



Detailed Description

The DS1865 integrates the control and monitoring functionality required to implement a PON system using Maxim's MAX3643 compact burst-mode laser driver. The compact laser driver solution offers a considerable cost benefit by integrating control and monitoring features in the low-power CMOS process, while leaving only the high-speed portions to the laser driver. Key components of the DS1865 are shown in the *Block Diagram* and described in subsequent sections. Table 1 contains a list of acronyms used in this data sheet.

APC Control

BIAS current is controlled by an average power control (APC) loop. The APC loop uses digital techniques to overcome the difficulties associated with controlling burst-mode systems.

Table 1. Acronyms

ACRONYM	DEFINITION
ADC	Analog-to-Digital Converter
APC	Average Power Control
ATB	Alarm Trap Bytes
DAC	Digital-to-Analog Converter
LUT	Lookup Table
NV	Nonvolatile
PON	Passive Optical Network
QT	Quick Trip
SEE	Shadowed EEPROM
TE	Tracking Error
TXP	Transmit Power

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The APC loop's feedback is the monitor diode (BMD) current, which is converted to a voltage using an external resistor. The feedback voltage is compared to an 8bit scaleable voltage reference that determines the APC set point of the system. Scaling of the reference voltage accommodates the wide range in photodiode sensitivities. This allows the application to take full advantage of the APC reference's resolution.

The DS1865 has an LUT to allow the APC set point to change as a function of temperature to compensate for tracking error (TE). The TE LUT (Table 05h) has 36 entries that determine the APC setting in 4°C windows between -40°C to +100°C. Ranging of the APC DAC is possible by programming a single byte in Table 02h.

Modulation Control

The MOD output is an 8-bit scaleable voltage output that interfaces with the MAX3643's VMSET input. An external resistor to ground from the MAX3643's MODSET pin sets the maximum current the voltage at VMSET input can produce for a given output range. This resistor value should be chosen to produce the maximum modulation current the laser type requires over temperature. Then the MOD output's scaling is used to calibrate the full-scale (FS) modulation output to a particular laser's requirements. This allows the application to take full advantage of the MOD output's resolution. The modulation LUT can be programmed in 2°C increments over the -40°C to +102°C range.

Ranging of the MOD DAC is possible by programming a single byte in Table 02h.

BIAS and MOD Output During Power-Up

On power-up, the modulation and bias outputs remain off until V_{CC} is above V_{POA} and a temperature conversion has been completed. If the V_{CC} LO ADC alarm is enabled, then a V_{CC} conversion above the customerdefined V_{CC} low alarm level is required before the outputs are enabled with the value determined by the temperature conversion and the modulation LUT.

When the MOD output is enabled and BEN is high, the BIAS output is turned on to a value equal to I_{STEP} (see Figure 1). The startup algorithm checks if this bias current causes a feedback voltage above the APC set point, and if it does not it continues increasing the BIAS by ISTEP until the APC set point is exceeded. When the APC set point is exceeded, the DS1865 begins a binary search to quickly reach the bias current corresponding to the proper power level. After the binary search is completed the APC integrator is enabled, and single LSB steps are taken to tightly control the average power.



All quick-trip alarm flags are masked until the binary search is completed. However, the BIAS MAX alarm is monitored during this time to prevent the bias output from exceeding MAX IBIAS. During the bias current initialization, the bias current is not allowed to exceed MAX IBIAS. If this occurs during the ISTEP sequence, the binary search routine begins. If MAX IBIAS is exceeded during the binary search, the next smaller step is activated. ISTEP or binary increments that would cause IBIAS to exceed MAX IBIAS are not taken. Masking the alarms until the completion of the binary search prevents false trips during startup.

ISTEP is programmed by the customer using the Startup Step register. This value should be programmed to the maximum safe current increase that is allowable during startup. If this value is programmed too low, the DS1865 will still operate, but it could take significantly longer for the algorithm to converge and hence to control the average power.

If a fault is detected and TX-D is toggled to re-enable the outputs, the DS1865 powers up following a similar sequence to an initial power-up. The only difference is that the DS1865 already has determined the present temperature, so the $t_{\rm INIT}$ time is not required for the DS1865 to recall the APC and MOD set points from EEPROM.

If the Bias-En bit (Table 02h, Register 80h) is written to 0, the BIAS DAC is manually controlled by the MAN IBIAS register (Table 02h, Registers F8h–F9h).

BIAS and MOD Output as a Function of Transmit Disable (TX-D)

If the TX-D pin is asserted (logic 1) during normal operation, the outputs are disabled within tOFF. When TX-D is deasserted (logic 0), the DS1865 turns on the MOD output with the value associated with the present temperature, and initializes the BIAS using the same search algorithm used at startup. When asserted, the soft TX-D (Lower Memory, Register 6Eh) offers a software control identical to the TX-D pin (see Figure 2).

APC and Quick-Trip Shared Comparator Timing

As shown in Figure 3, the DS1865's input comparator is shared between the APC control loop and the three quick-trip alarms (TXP-HI, TXP-LO, and BIAS HI). The comparator polls the alarms in a round-robin multiplexed sequence. Six of every eight comparator readings are used for APC loop-bias current control. The other two updates are used to check the HTXP/LTXP (monitor diode voltage) and the HBIAS (MON1) signals against the internal APC and BIAS reference. The HTXP/LTXP comparison checks HTXP to see if the last

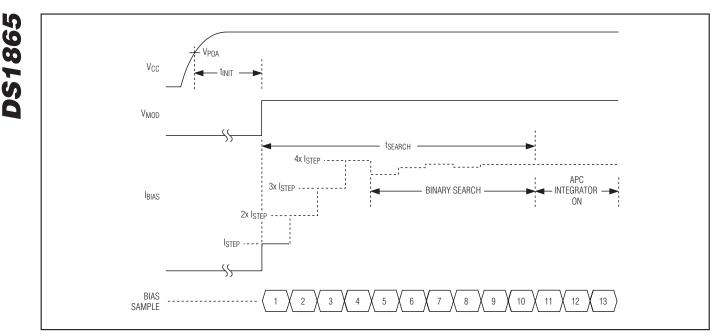


Figure 1. Power-Up Timing

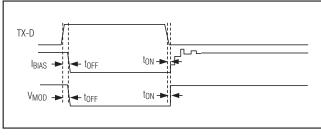


Figure 2. TX-D Timing (Normal Operating Conditions)

bias update comparison was above the APC set point, and checks LTXP to see if the last bias update comparison was below the APC set point. Depending on the results of the comparison, the corresponding alarms and warnings (TXP-HI, TXP-LO) are asserted or deasserted.

The DS1865 has a programmable comparator sample time based on an internally generated clock to facilitate a wide variety of external filtering options suitable for burst-mode transmitter data rates between 155Mbps and 1250Mbps. The rising edge of the burst enable (BEN) triggers the sample to occur, and the Update Rate register (Table 02h, Register 88h) determines the sampling time. The first sample occurs t_{FIRST} after the rising edge of BEN. The internal clock is asynchronous to BEN, causing a ± 50 ns uncertainty regarding when the first sample will occur following BEN. After the first sample occurs, subsequent samples occur on a regular interval, t_{REP}. Table 2 shows the sample rate options available.

Table 2. Update Rate Timing

SR3-SR0	MINIMUM TIME FROM BEN TO FIRST SAMPLE (t _{FIRST}) ±50ns	REPEATED SAMPLE PERIOD FOLLOWING FIRST SAMPLE (t _{REP})
0000b	350ns	800ns
0001b	550ns	1200ns
0010b	750ns	1600ns
0011b	950ns	2000ns
0100b	1350ns	2800ns
0101b	1550ns	3200ns
0110b	1750ns	3600ns
0111b	2150ns	4400ns
1000b	2950ns	6000ns
1001b*	3150ns	6400ns

*All codes greater than 1001b (1010b–1111b) use the maximum sample time of code 1001b.

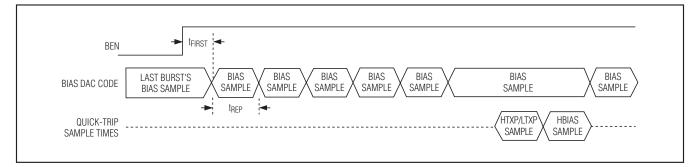


Figure 3. APC and Quick-Trip Alarm Sample Timing

Updates to the TXP-HI, TXP-LO, and BIAS HI quick-trip alarms do not occur during the burst-enable low time. Any quick-trip alarm that is detected by default remains active until a subsequent comparator sample shows the condition no longer exists.

A second bias-current monitor (BIAS MAX) compares the DS1865's BIAS DAC's code to a digital value stored in the MAX IBIAS register. This comparison is made every bias-current update to ensure that a high bias current is quickly detected.

Monitors and Fault Detection

Monitors

Monitoring functions on the DS1865 include four quicktrip comparators and six ADC channels. This monitoring, combined with the interrupt masks, determines when/if the DS1865 shuts down its outputs and triggers the TX-F and FETG outputs. All the monitoring levels and interrupt masks are user programmable.

Four Quick-Trip Monitors and Alarms

Four quick-trip monitors are provided to detect potential laser safety issues. These monitor:

- 1) High Bias Current (HBIAS)
- 2) Low Transmit Power (LTXP)
- 3) High Transmit Power (HTXP)
- 4) Max Output Current (MAX IBIAS)

The high and low transmit power quick-trip registers (HTXP and LTXP) set the thresholds used to compare against the BMD voltage to determine if the transmit power is within specification. The HBIAS quick-trip compares the MON1 input (generally from the MAX3643 bias monitor output) against its threshold setting to determine if the present bias current is above specification. The BIAS MAX quick-trip is a digital comparison that determines if the BIAS DAC indicates that the bias



current is above specification. I_{BIAS} is not allowed to exceed the value set in the MAX IBIAS register. When the DS1865 detects that the bias is at the limit, it sets the BIAS MAX status bit and holds the bias current at the MAX IBIAS level. The quick-trips are routed to the TX-F and FETG outputs through interrupt masks to allow combinations of these alarms to be used to trigger these outputs. When FETG is triggered, the DS1865 also disables the MOD and BIAS outputs. See the *BIAS and MOD Output During Power-Up* section for details.

Six ADC Monitors And Alarms

The ADC monitors six channels that measure temperature (internal temp sensor), V_{CC}, MON1, MON2, MON3, and MON4 using an analog multiplexer to measure them round-robin with a single ADC. Each channel has a customer-programmable full-scale range and offset value that is factory programmed to a default value (see Table 3). Additionally, MON1–MON4 can right shift results by up to 7 bits before the results are compared to alarm thresholds or read over the I²C bus. This allows customers with specified ADC ranges to calibrate the ADC full scale to a factor of 1/2ⁿ of their specified range to measure small signals. The DS1865 can then right shift the results by n bits to maintain the bit weight of their specification.

Table 3.	ADC	Default	Monitor	Full-Scale
Ranges				

SIGNAL (UNITS)	+FS SIGNAL	+FS HEX	-FS SIGNAL	-FS HEX
Temperature (°C)	127.996	7FFF	-128	8000
V _{CC} (V)	6.5528	FFF8	0V	0000
MON1-MON4 (V)	2.4997	FFF8	0V	0000

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The ADC results (after right shifting, if used) are compared to high alarm thresholds, low alarm thresholds, and the warning threshold after each conversion, and the corresponding alarms are set, which can be used to trigger the TX-F or FETG outputs. These ADC thresholds are user programmable, as are the masking registers that can be used to prevent the alarms from triggering the TX-F and FETG outputs.

ADC Timing There are six analog channels that are digitized in a round-robin fashion in the order as shown in Figure 4. The total time required to convert all six channels is t_{RR} (see *Timing Characteristics (Control Loop and Quick-Trip)* for details).

Right Shifting ADC Result

If the weighting of the ADC digital reading must conform to a predetermined full-scale value defined by a standard's specification, then right shifting can be used to adjust the predetermined full-scale analog measurement range while maintaining the weighting of the ADC results. The DS1865's range is wide enough to cover all requirements; when the maximum input value is far short of the FS value, right shifting can be used to obtain greater accuracy. For instance, the maximum voltage might be 1/8th the specified predetermined fullscale value, so only 1/8th the converter's range is used. An alternative is to calibrate the ADC's full-scale range to 1/8th the readable predetermined full-scale value and use a right-shift value of 3. With this implementation, the resolution of the measurement is increased by a factor of 8, and because the result is digitally divided by 8 by right shifting, the bit weight of the measurement still meets the standard's specification (i.e., SFF-8472).

The right-shift operation on the ADC result is carried out based on the contents of Right Shift Control registers (Table 02h, Registers 8Eh-8Fh) in EEPROM. Four analog channels, MON1–MON4, each have 3 bits allocated to set the number of right shifts. Up to 7 right-shift operations are allowed and are executed as a part of every conversion before the results are compared to the high and low alarm levels, or loaded into their corresponding measurement registers (Table 01h, Registers 62h–6Bh). This is true during the setup of internal calibration as well as during subsequent data conversions.

Transmit Fault (TX-F) Output

The TX-F output has masking registers for the six ADC alarms and the four QT alarms to select which comparisons cause it to assert. In addition, the FETG alarm is selectable through the TX-F mask to cause TX-F to assert. All alarms, with the exception of FETG, only cause TX-F to remain active while the alarm condition persists. However, the TX-F latch bit can enable the TX-F output to remain active until it is cleared by the TX-F reset bit, TX-D, soft TX-D, or by power cycling the part. If the FETG output is configured to trigger TX-F, it indicates that the DS1865 is in shutdown, and requires TX-D, soft TX-D, or cycling power to reset. The QT alarms are masked until the completion of the binary search. Only enabled alarms will activate TX-F. See Figure 5.

Table 4 shows TX-F as a function of TX-D and the alarm sources.

Safety Shutdown (FETG) Output

The FETG output has masking registers (separate from TX-F) for the five ADC alarms and the four QT alarms to select which comparisons cause it to assert. Unlike TX-F, the FETG output is always latched in case it is triggered by an unmasked alarm condition. Its output polarity is programmable to allow an external nMOSFET or pMOSFET to open during alarms to shut off the laser diode current. If the FETG output triggers, indicating that the DS1865 is in shutdown, it requires TX-D, soft TX-D, or cycling power to be reset. Under all conditions, when the analog outputs are reinitialized after being disabled, all the alarms with the exception of the V_{CC} low ADC alarm are cleared. The V_{CC} low alarm must remain active to prevent the output from attempting to operate when

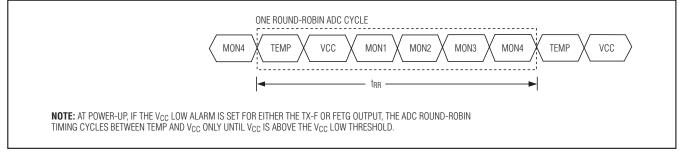


Figure 4. ADC Round-Robin Timing

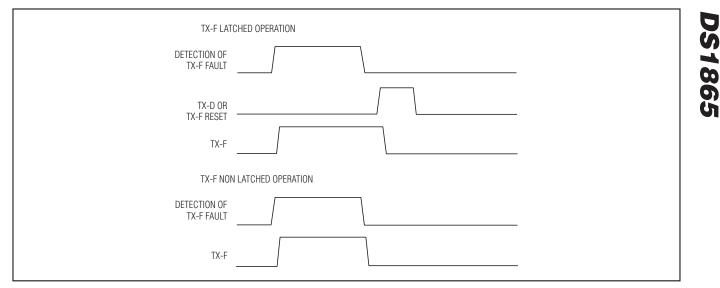


Figure 5. TX-F Timing

Table 4. TX-F as a Function of TX-D andAlarm Sources

V _{CC} > V _{POA}	TX-D	NONMASKED TX-F ALARM	TX-F
No	Х	Х	1
Yes	0	0	0
Yes	0	1	1
Yes	1	Х	0

inadequate V_{CC} exists to operate the laser driver. Once adequate V_{CC} is present to clear the V_{CC} low alarm, the outputs are enabled following the same sequence as the power-up sequence.

As previously mentioned, the FETG is an output used to disable the laser current through a series nMOSFET or pMOSFET. This requires that the FETG output can sink or source current. Because the DS1865 does not know if it should sink or source current before V_{CC} exceeds V_{POA}, which triggers the EE recall, this output will be high impedance when V_{CC} is below V_{POA} (see the *Low-Voltage Operation* section for details and diagram). The application circuit must use a pullup or pulldown resistor on this pin that pulls FETG to the alarm/shutdown state (high for a pMOS, low for a nMOS). Once V_{CC} is above V_{POA}, the DS1865 pulls the FETG output to the state determined by the FETG DIR bit (Table 02h, Register 89h). FETG DIR is 0 if an nMOS is used and 1 if a pMOS is used.



Determining Alarm Causes Using the I²C Interface

To determine the cause of the TX-F or FETG alarm, the system processor can read the DS1865's Alarm Trap Bytes (ATB) through the I²C interface (in Table 01h). The ATB has a bit for each alarm. Any time an alarm occurs, regardless of the mask bit's state, the DS1865 sets the corresponding bit in the ATB. Active ATB bits remain set until written to zeros through the I²C interface. On power-up, the ATB is zeros until alarms dictate otherwise.

Die Identification

The DS1865 has an ID hard coded to its die. Two registers (Table 02h bytes 86h–87h) are assigned for this feature. Byte 86h reads 65h to identify the part as the DS1865, byte 87h reads the die revision.

Low-Voltage Operation

The DS1865 contains two power-on reset (POR) levels. The lower level is a digital POR (V_{POD}) and the higher level is an analog POR (V_{POA}). At startup, before the supply voltage rises above V_{POA}, the outputs are disabled (FETG and BIAS outputs are high impedance, MOD is low), all SRAM locations are low (including shadowed EEPROM), and all analog circuitry is disabled. When V_{CC} reaches V_{POA}, the SEE is recalled, and the analog circuitry is enabled. While V_{CC} remains above V_{POA}, the device is in its normal operating state, and it responds based on its nonvolatile configuration. If during operation V_{CC} falls below V_{POA} but is still above V_{POD}, the SRAM retains the SEE settings from

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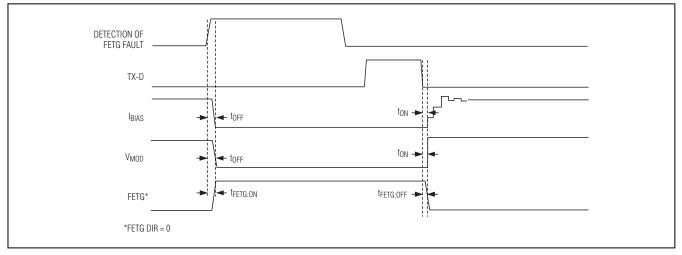


Figure 6. FETG/Modulation and Bias Timing (Fault Condition Detected)

Table 5. FETG, MOD, and BIAS Outputs as a Function of TX-D and Alarm Sources

V _{CC} > V _{POA}	TX-D	NONMASKED FETG ALARM	FETG	MOD AND BIAS OUTPUTS
Yes	0	0	FETG DIR	Enabled
Yes	0	1	FETG DIR	Disabled
Yes	1	Х	FETG DIR	Disabled

the first SEE recall, but the device analog is shut down and the outputs are disabled. FETG is driven to its alarm state defined by the FETG DIR bit (Table 02h, Register 89h). If the supply voltage recovers back above VPOA, the device immediately resumes normal functioning. If the supply voltage falls below VPOD, the device SRAM is placed in its default state and another SEE recall is required to reload the nonvolatile settings. The EEPROM recall occurs the next time V_{CC} exceeds VPOA. Figure 7 shows the sequence of events as the voltage varies.

Any time V_{CC} is above V_{POD}, the I²C interface can be used to determine if V_{CC} is below the V_{POA} level. This is accomplished by checking the RDYB bit in the status (Lower Memory, Register 6Eh) byte. RDYB is set when V_{CC} is below V_{POA}. When V_{CC} rises above V_{POA}, RDYB is timed (within 500µs) to go to 0, at which point the part is fully functional. For all device addresses sourced from EEPROM (Table 02h, Register 8Ch), the default device address is A2h until V_{CC} exceeds V_{POA} allowing the device address to be recalled from the EEPROM.

Power-On Analog (POA)

POA holds the DS1865 in reset until V_{CC} is at a suitable level (V_{CC} > V_{POA}) for the part to accurately measure with its ADC and compare analog signals with its quicktrip monitors. Because V_{CC} cannot be measured by the ADC when V_{CC} is less than V_{POA}, POA also asserts the V_{CC} low alarm, which is cleared by a V_{CC} ADC conversion greater than the customer-programmable V_{CC} low ADC limit. This prevents the TX-F and FETG outputs from glitching during a slow power-up. The TX-F and FETG outputs do not latch until there is a conversion above V_{CC} low limit.

The POA alarm is nonmaskable. The TX-F and FETG outputs are asserted when V_{CC} is below V_{POA}. See the *Low-Voltage Operation* section for more information.

DAC1 Output

The DAC1 output has a 0 to 2.5V range, 8 bits of resolution, and is programmed through the $\rm I^2C$ interface. The DAC1 setting is nonvolatile and password 2 (PW2) protected.

M4DAC Output

The M4DAC output has a 0 to 2.5V range, 8 bits of resolution, and is controlled by an LUT indexed by the MON4 voltage. The M4DAC LUT (Table 06h) is non-volatile and PW2 protected. See the *Memory Organization* section for details.

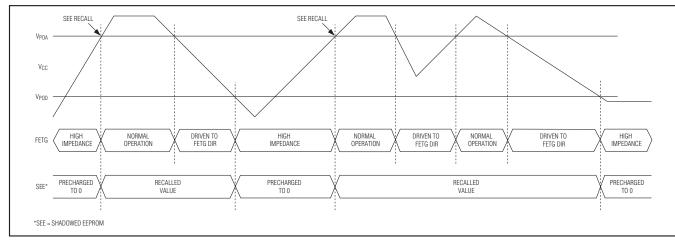


Figure 7. Low-Voltage Hysteresis Example

Digital I/O Pins

Five digital I/O pins are provided for additional monitoring and control of the triplexer. By default the LOSI pin is used to convert a standard comparator output for loss of signal (LOSI) to an open-collector output. This means the mux shown on the block diagram by default selects the LOSI pin as the source for the D0 output transistor. The level of the D0 pin can be read in the status byte (Lower Memory, Register 6Eh) as the LOS status bit. The LOS status bit reports back the logic level of the D0 pin, so an external pullup resistor must be provided for this pin to output a high level. The LOSI signal can be inverted before driving the open-drain output transistor using the XOR gate provided. The mux LOSI allows the D0 pin to be used identically to the D1, D2, and D3 pins. However, the mux setting (stored in the EEPROM) does not take effect until $V_{CC} > V_{POA}$, allowing the EEPROM to recall. This requires the LOSI pin to be grounded for D0 to act identical to the D1, D2, and D3 pins.

Digital pins D1, D2, and D3 can be used as inputs or outputs. External pullup resistors must be provided to realize high logic levels. The levels of these input pins can be read by reading the DIN byte (Lower Memory, Register 79h), and the open-drain outputs can be controlled using the DOUT byte (Lower Memory, Register 78h). When V_{CC} < V_{POA}, these outputs are high impedance. Once V_{CC} \geq V_{POA}, the outputs go to the power-on default state stored in the DPU byte (Table 02h, Register C0h). The EEPROM determined default state of the pin can be modified with PW2 access. After the default state has been recalled, the SRAM registers controlling outputs can be modified without password access. This allows the outputs to be used to control serial interfaces without wearing out the default EEPROM setting.

Memory Organization

DS1865

The DS1865 features eight banks of memory composed of the following.

The **Lower Memory** is addressed from 00h to 7Fh and contains alarm and warning thresholds, flags, masks, several control registers, password entry area (PWE), and the table select byte. The table select byte determines which table (01h–06h) will be mapped into the upper memory locations, namely 80h–FFh (unless stated otherwise).

Table 01h primarily contains user EEPROM (with PW1 level access) as well as some alarm and warning status bytes.

Table 02h is a multifunction space that contains configuration registers, scaling and offset values, passwords, interrupt registers, as well as other miscellaneous control bytes.

Table 03h is strictly user EEPROM that is protected by a PW2 level access.

Table 04h contains a temperature-indexed LUT for control of the modulation voltage. The modulation LUT can be programmed in 2°C increments over the -40°C to +102°C range. This register is protected by a PW2 level access.

Table 05h contains another LUT, which allows the APC set point to change as a function of temperature to compensate for tracking error (TE). This TE LUT has 36 entries that determine the APC setting in 4°C windows between -40°C to +100°C. This register is protected by a PW2 level access.

BALLAS SEMICONDUCTOR

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DS1865

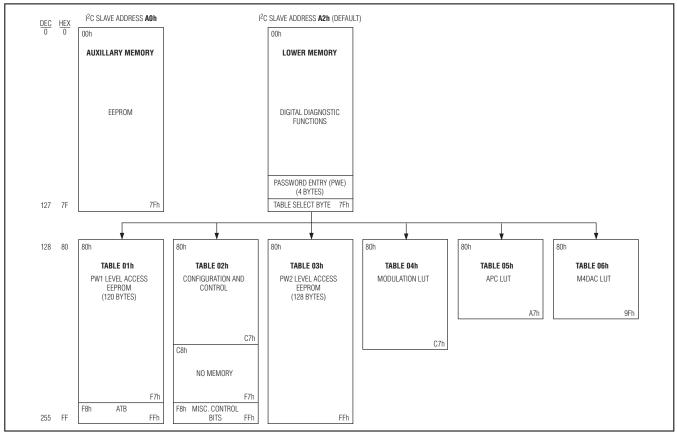


Figure 8. Memory Map

Table 06h contains a MON4-indexed LUT for control of the M4DAC voltage. The M4DAC LUT has 32 entries that are configurable to act as one 32-entry LUT or two 16-entry LUTs. When configured as one 32-byte LUT, each entry corresponds to an increment of 1/32 of the full scale. When configured as two 16-byte LUTs, the first 16 bytes and the last 16 bytes each correspond to 1/16 of full scale. Either of the two sections is selected with a separate configuration bit. This LUT is protected by a PW2 level access.

Auxiliary Memory is EEPROM accessible at the I²C slave address, A0h.

See the register map tables for a more complete detail of each byte's function, as well as for read/write permissions for each byte.

Shadowed EEPROM

In addition to volatile memory (SRAM) and nonvolatile memory (EEPROM), the DS1865 also features shadowed

EEPROM. Shadowed EEPROM (SEE) can be configured as either volatile or nonvolatile memory using the SEEB bit in Table 02h, Register 80h.

The DS1865 uses shadowed EEPROM memory for key memory addresses that can be rewritten many times. By default the shadowed EEPROM bit, SEEB, is not set and these locations act as ordinary EEPROM. By setting SEEB, these locations function like SRAM cells, which allow an infinite number of write cycles without concern of wearing out the EEPROM. This also eliminates the requirement for the EEPROM write time, twp. Because changes made with SEEB enabled do not affect the EEPROM, these changes are not retained through power cycles. The power-up value is the last value written with SEEB disabled. This function can be used to limit the number of EEPROM writes during calibration or to change the monitor thresholds periodically during normal operation, helping to reduce the number of times EEPROM is written. The Memory Organization description indicates which locations are shadowed EEPROM.



_I²C Definitions

The following terminology is commonly used to describe I²C data transfers.

Master Device: The master device controls the slave devices on the bus. The master device generates SCL clock pulses and START and STOP conditions.

Slave Devices: Slave devices send and receive data at the master's request.

Bus Idle or Not Busy: Time between STOP and START conditions when both SDA and SCL are inactive and in their logic-high states. When the bus is idle, it often initiates a low-power mode for slave devices.

START Condition: A START condition is generated by the master to initiate a new data transfer with a slave. Transitioning SDA from high to low while SCL remains high generates a START condition. See Figure 9 for applicable timing.

STOP Condition: A STOP condition is generated by the master to end a data transfer with a slave. Transitioning SDA from low to high while SCL remains high generates a STOP condition. See Figure 9 for applicable timing.

Repeated START Condition: The master can use a repeated START condition at the end of one data transfer to indicate that it will immediately initiate a new data transfer following the current one. Repeated START conditions are commonly used during read operations to identify a specific memory address to begin a data transfer. A repeated START condition is issued identically to a normal START condition. See Figure 9 for applicable timing.

Bit Write: Transitions of SDA must occur during the low state of SCL. The data on SDA must remain valid and unchanged during the entire high pulse of SCL plus the setup and hold-time requirements (Figure 9). Data is shifted into the device during the rising edge of the SCL.

Bit Read: At the end of a write operation, the master must release the SDA bus line for the proper amount of setup time before the next rising edge of SCL during a bit read. The device shifts out each bit of data on SDA at the falling edge of the previous SCL pulse and the data bit is valid at the rising edge of the current SCL pulse. Remember that the master generates all SCL clock pulses including when it is reading bits from the slave.

Acknowledgement (ACK and NACK): An acknowledgement (ACK) or not acknowledge (NACK) is always the 9th bit transmitted during a byte transfer. The device receiving data (the master during a read or the slave during a write operation) performs an ACK by transmitting a zero during the 9th bit. A device performs a NACK by transmitting a one during the 9th bit. Timing for the ACK and NACK is identical to all other bit writes. An ACK is the acknowledgment that the device is properly receiving data. A NACK is used to terminate a read sequence or as an indication that the device is not receiving data.

Byte Write: A byte write consists of 8 bits of information transferred from the master to the slave (most significant bit first) plus a 1-bit acknowledgement from the slave to the master. The 8 bits transmitted by the master are done according to the bit write definition and the acknowledgement is read using the bit read definition.

Byte Read: A byte read is an 8-bit information transfer from the slave to the master plus a 1-bit ACK or NACK from the master to the slave. The 8 bits of information that are transferred (most significant bit first) from the slave to the master are read by the master using the bit read definition, and the master transmits an ACK using the bit write definition to receive additional data bytes. The master must NACK the last byte read to terminate communication so the slave returns control of SDA to the master.

Slave Address Byte: Each slave on the I²C bus responds to a slave addressing byte (Figure 9) sent immediately following a START condition. The slave address byte contains the slave address in the most significant 7 bits and the R/W bit in the least significant bit.

The DS1865 responds to two slave addresses. The auxiliary memory always responds to a fixed I²C slave address, A0h. The Lower Memory and tables 01h–06h respond to I²C slave addresses that can be configured to any value between 00h–FEh using the Device Address byte (Table 02h, Register 8Ch). The user also must set the ASEL bit (Table 02h, Register 89h) for this address to be active. By writing the correct slave address with R/W = 0, the master indicates it will write data to the slave. If R/W = 1, the master reads data from the slave. If an incorrect slave address is written, the DS1865 assumes the master is communications until the next START condition is sent.

Memory Address: During an I²C write operation, the master must transmit a memory address to identify the memory location where the slave is to store the data. The memory address is always the second byte transmitted during a write operation following the slave address byte.

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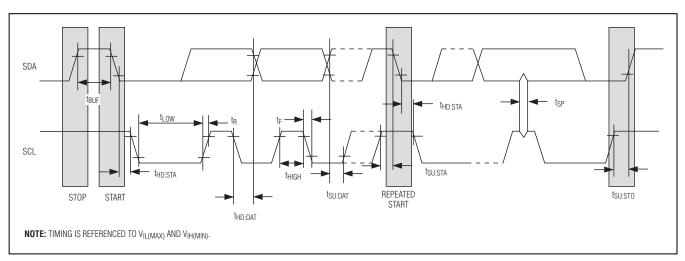


Figure 9. I²C Timing Diagram

_I²C Communication

Writing a Single Byte to a Slave: The master must generate a START condition, write the I²C slave address byte ($R/\overline{W} = 0$), write the byte of data, and generate a STOP condition. The master must read the slave's acknowledgement during all byte write operations.

Writing Multiple Bytes to a Slave: To write multiple bytes to a slave, the master generates a START condition, writes the slave address byte (R/W = 0), writes the memory address, writes up to 8 data bytes, and generates a STOP condition. The DS1865 writes 1 to 8 bytes (1 page or row) with a single write transaction. This is internally controlled by an address counter that allows data to be written to consecutive addresses without transmitting a memory address before each data byte is sent. The address counter limits the write to one 8-byte page (one row of the memory map). Attempts to write to additional pages of memory without sending a STOP condition between pages result in the address counter wrapping around to the beginning of the present row.

Example: A 3-byte write starts at address 06h and writes three data bytes (11h, 22h, and 33h) to three "consecutive" addresses. The result is that addresses 06h and 07h contain 11h and 22h, respectively, and the third data byte, 33h, is written to address 00h.

To prevent address wrapping from occurring, the master must send a STOP condition at the end of the page, then wait for the bus-free or EEPROM-write time to elapse. Then the master can generate a new START condition, and write the slave address byte (R/W = 0) and the first memory address of the next memory row before continuing to write data.

Acknowledge Polling: Any time an EEPROM location is written, the DS1865 requires the EEPROM write time (t_W) after the STOP condition to write the contents of the byte of data to EEPROM. During the EEPROM write time, the device does not acknowledge its slave address because it is busy. It is possible to take advantage of that phenomenon by repeatedly addressing the DS1865, which allows the next page to be written as soon as the DS1865 is ready to receive the data. The alternative to acknowledge polling is to wait for a maximum period of t_W to elapse before attempting to write again to the DS1865.

EEPROM Write Cycles: When EEPROM writes occur to the memory, the DS1865 writes to all three EEPROM memory locations, even if only a single byte was modified. Because all three bytes are written, the bytes that were not modified during the write transaction are still subject to a write cycle. This can result in all three bytes being worn out over time by writing a single byte repeatedly. The DS1865's EEPROM write cycles are specified in the *Nonvolatile Memory Characteristics* table. The specification shown is at the worst-case temperature. It can handle approximately 10 times that many writes at room temperature. Writing to SRAMshadowed EEPROM memory with SEEB = 1 does not count as an EEPROM write cycle when evaluating the EEPROM's estimated lifetime.

Reading a Single Byte from a Slave: Unlike the write operation that uses the memory address byte to define where the data is to be written, the read operation occurs at the present value of the memory address counter. To read a single byte from the slave, the master generates a START condition, writes the slave address byte with R/W = 1, reads the data byte with a NACK to indicate the end of the transfer, and generates a STOP condition.

Manipulating the Address Counter for Reads: $\mbox{\sc A}$

dummy write cycle can be used to force the address pointer to a particular value. To do this, the master generates a START condition, writes the slave address byte ($R/\overline{W} = 0$), writes the memory address where it desires to read, generates a repeated START condition, writes the slave address byte ($R/\overline{W} = 1$), reads data with ACK or NACK as applicable, and generates a STOP condition.

Register Maps

Lower Memory Register Map

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This register map shows each byte/word in terms of the row it is on in the memory. The first byte in the row is located in memory at the hexadecimal row address in the left-most column. Each subsequent byte on the row is one/two memory locations beyond the previous byte/word's address. A total of 8 bytes are present on each row. For more information about each of these bytes, see the corresponding register description in the following tables.

				LOWER I	MEMORY				
ROW	ROW	WOF	RD 0	WOF	WORD 1		RD 2	WOF	RD 3
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F
00	<1>THRESHOLD0	TEMP AI	_ARM HI	TEMP AL	ARM LO	TEMP V	/ARN HI	TEMP W	ARN LO
08	<1>THRESHOLD1	VCC AL	ARM HI	VCC ALA	ARM LO	VCC W	ARN HI	VCC W	ARN LO
10	<1>THRESHOLD ₂	MON1 A	LARM HI	MON1 AL	ARM LO	MON1 V	VARN HI	MON1 W	/ARN LO
18	<1>THRESHOLD3	MON2 A	LARM HI	MON2 AL	ARM LO	MON2 V	VARN HI	MON2 W	/ARN LO
20	<1>THRESHOLD4	MON3 A	LARM HI	MON3 AL	I3 ALARM LO		MON3 WARN HI		/ARN LO
28	<1>THRESHOLD5	MON4 A	LARM HI	MON4 ALARM LO		MON4 WARN HI		MON4 WARN LO	
30	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
38	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
40	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
48	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
50	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
58	<1>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
60	<2>ADC VALUES0	TEMP	VALUE	VCC V	ALUE	MON1	VALUE	MON2	VALUE
68	<0> ADC VALUES1	<2>MON	3 VALUE	<2> MON4 VALUE		<2>RES	ERVED	<0>STATUS	<3>UPDATE
70	<2>ALARM/WARN	ALARM3	ALARM2	ALARM1	ALARM ₀	WARN3	WARN ₂	RESE	RVED
78	<0>TABLE SELECT	<2>DOUT	<2>DIN	<6>RESERVED	<6>PW	E MSB	<6>PW	ELSB	<5>TBL SEL

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access		All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 01h Register Map

				TABLE 01	h (PW1)						
ROW	ROW	WOF	RD 0	WO	RD 1	WOF	RD 2	WOF	WORD 3		
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F		
80	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
88	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
90	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
98	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
A0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
A8	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
B0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
B8	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
C0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
C8	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
D0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
D8	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
E0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
E8	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
F0	<7>PW1 EE	EE	EE	EE	EE	EE	EE	EE	EE		
F8	<11>ALARM TRAP	ALARM3	ALARM2	ALARM1	ALARM0	WARN3	WARN ₂	RESE	RVED		

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access		All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 02h Register Map

DS1865

	TABLE 02h (PW2)											
ROW	ROW	WOF	RD 0	WORD 1		WOF	RD 2	WO	WORD 3			
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F			
80	<0> CONFIG0	<8>MODE	<4>T INDEX	<4> MOD DAC	APC DAC	<4> V INDEX	<4> M4DAC	<10> DEVICE ID	<10> DEVICE VER			
88	<8> CONFIG1	UPDATE RATE	CONFIG	STARTUP STEP	MOD RANGING	DEVICE ADDRESS	COMP RANGING	RSHIFT ₁	RSHIFT ₀			
90	SCALE0	RESE	RESERVED		V _{CC} SCALE		MON1 SCALE		MON2 SCALE			
98	<8> SCALE1	MON3	MON3 SCALE		MON4 SCALE		RESERVED		RESERVED			
AO	<8> OFFSET0	RESE	RVED	V _{CC} OFFSET		MON1 OFFSET		MON2 OFFSET				
A8	<8> OFFSET1	MON3 (OFFSET	MON4 (OFFSET	RESERVED		INTERNAL TEMP OFFSET*				
BO	PWD VALUE	PW1	MSW	PW1	LSW	PW2	MSW	PW2	LSW			
B8	<8> INTERRUPT	FETG EN1	FETG EN0	TX-F EN1	TX-F EN0	HTXP	LTXP	HBIAS	MAX IBIAS			
CO	<8> CNTL OUT	DPU	RESERVED	RESERVED	RESERVED	DAC1	RESERVED	RESERVED	M4 LUT CNTL			
C8-F7	EMPTY	EMPTY	EMPTY	EMPTY	EMPTY	EMPTY	EMPTY	EMPTY	EMPTY			
F8	MAN IBIAS	<4> MAN IBIAS ₁	<4> MAN IBIASO	<4> MAN_CNTL	<10> BIAS DAC1	<10> BIAS DAC0	RESERVED	RESERVED	RESERVED			

*The final result must be XORed with BB40h before writing to this register.

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access	0	All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 03h Register Map

				TABLE 03	h (PW3)				
ROW	ROW	WOF	RD 0	WO	RD 1	WOF	RD 2	WOF	RD 3
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F
80	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
88	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
90	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
98	<8>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
AO	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
A8	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
B0	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
B8	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
C0	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
C8	<8>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
D0	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
D8	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
E0	<8>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
E8	^{<8>} PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
F0	<8>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE
F8	<8>PW2 EE	EE	EE	EE	EE	EE	EE	EE	EE

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access		All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 04h Register Map

				TABLE 04h ((MOD LUT)				
ROW	ROW	WOF	RD 0	WOF	RD 1	WOF	RD 2	WOF	RD 3
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F
80	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
88	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
90	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
98	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
AO	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
A8	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
BO	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
B8	<8>LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD
C0	^{<8>} LUT4	MOD	MOD	MOD	MOD	MOD	MOD	MOD	MOD

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access	0	All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 05h Register Map

				TABLE 05h (APC LUT)				
ROW	ROW	WOF	RD 0	WOF	RD 1	WOF	RD 2	WOF	RD 3
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F
80	<8>LUT5	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF
88	<8>LUT5	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF
90	<8>LUT5	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF
98	<8>LUT5	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF	APC REF
A0	<8>LUT5	APC REF	APC REF	APC REF	APC REF	RESERVED	RESERVED	RESERVED	RESERVED

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access	0	All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

Table 06h Register Map

			TAE	BLE 06h (LUT	FOR M4DA	C)				
ROW	ROW	WOF	RD 0	WOF	RD 1	WOF	RD 2	WORD 3		
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F	
80	<8>LUT6	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	
88	<8>LUT6	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	
90	<8>LUT6	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	
98	<8>LUT6	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	M4DAC	

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access		All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

AUX A0h Memory Register Map

	AUX MEMORY (A0h)											
ROW	ROW	WOF	RD 0	WOF	RD 1	WO	RD 2	WOF	RD 3			
(HEX)	NAME	BYTE 0/8	BYTE 1/9	BYTE 2/A	BYTE 3/B	BYTE 4/C	BYTE 5/D	BYTE 6/E	BYTE 7/F			
00	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
08	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
10	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
18	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
20	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
28	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
30	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
38	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
40	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
48	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
50	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
58	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
60	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
68	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
70	AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			
78	<5>AUX EE	EE	EE	EE	EE	EE	EE	EE	EE			

ACCESS CODE	<0>	<1>	<2>	<3>	<4>	<5>	<6>	<7>	<8>	<9>	<10>	<11>
Read Access		All	All	All	PW2	All	N/A	PW1	PW2	N/A	PW2	All
Write Access	See each bit/byte separately	PW2	N/A	All and DS1865 hardware	PW2 + mode bit	All	All	PW1	PW2	PW2	N/A	PW1

BALLAS JUINKI/

Lower Memory Registers

Lower Memory, Register 00h to 01h: Temp Alarm Hi Lower Memory, Register 04h to 05h: Temp Warn Hi

FACTORY DE	FAULT:	7FFFh						
READ ACCES	S	All						
WRITE ACCES	SS	PW2						
MEMORY TYP	PE:	Nonvolat	ile (SEE)					
00h, 04h	S	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
01h, 05h	2-1	2-2	2-3	2-4	2-5	2-6	2-7	2-8
	bit7							bit0

Temperature measurement updates above this two's complement threshold will set its corresponding alarm or warning bit. Temperature measurement updates equal to or below this threshold will clear its alarm or warning bit.

Lower Memory, Register 02h to 03h: Temp Alarm Lo Lower Memory, Register 06h to 07h: Temp Warn Lo

FACTORY DE	FAULT:	8000h	000h							
READ ACCES	S	All								
WRITE ACCES	SS	PW2								
MEMORY TYPE:		Nonvolat	Nonvolatile (SEE)							
02h, 06h	S	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2º		
03h, 07h	2-1	2 ⁻²	2 ⁻³	2-4	2-5	2-6	2-7	2-8		
	bit7							bit0		

Temperature measurement updates above this two's complement threshold will set its corresponding alarm or warning bit. Temperature measurement updates equal to or below this threshold will clear its alarm or warning bit.

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Lower Memory, Register 08h to 09h: V_{cc} Alarm Hi Lower Memory, Register 0Ch to 0dh: V_{cc} Warn Hi Lower Memory, Register 10h to 11h: MON1 Alarm Hi Lower Memory, Register 14h to 15h: MON1 Warn Hi Lower Memory, Register 18h to 19h: MON2 Alarm Hi Lower Memory, Register 1Ch to 1Dh: MON2 Warn Hi Lower Memory, Register 20h to 21h: MON3 Alarm Hi Lower Memory, Register 24h to 25h: MON3 Warn Hi Lower Memory, Register 28h to 29h: MON4 Alarm Hi Lower Memory, Register 2Ch to 2Dh: MON4 Warn Hi

FACTORY DEFA	AULT:	FFFFh				
READ ACCESS		All				
WRITE ACCESS	5	PW2				
MEMORY TYPE:	:	Nonvolat	tile (SEE)			
08, 0C, 10, 14, 18, 1C,	O ¹⁵	014	013			

08, 0C, 10, 14, 18, 1C, 20, 24, 28, 2Ch	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2°	2 ⁸
09, 0D, 11, 15, 19, 1D, 21, 25, 29, 2Dh	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2º
	bit7							bit0

Voltage measurement updates above this unsigned threshold will set its corresponding alarm or warning bit. Voltage measurements equal to or below this threshold will clear its alarm or warning bit.

Lower Memory, Register 0Ah to 0Bh: Vcc Alarm Lo Lower Memory, Register 0Eh to 0Fh: Vcc Warn Lo Lower Memory, Register 12h to 13h: MON1 Alarm Lo Lower Memory, Register 16h to 17h: MON1 Warn Lo Lower Memory, Register 1Ah to 1Bh: MON2 Alarm Lo Lower Memory, Register 1Eh to 1Fh: MON2 Warn Lo Lower Memory, Register 22h to 23h: MON3 Alarm Lo Lower Memory, Register 26h to 27h: MON3 Warn Lo Lower Memory, Register 2Ah to 2Bh: MON4 Alarm Lo Lower Memory, Register 2Eh to 2Fh: MON4 Warn Lo

FACTORY DEFAULT:	0000h
READ ACCESS	All
WRITE ACCESS	PW2

MEMORY TYPE.

Nonvolatile (SEE)

	Έ.	Norivolat	lie (SEE)						
0A, 0E, 12, 16, 1A, 1E, 22, 26, 2A, 2Eh	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2°	2 ⁸	
0B, 0F, 13, 17, 1B, 1F, 23, 27, 2B, 2Fh	27	2 ⁶	2 ⁵	2^4	2 ³	2 ²	2 ¹	2°	
	bit7	•		•				bit0	-

Voltage measurement updates above this unsigned threshold will set its corresponding alarm or warning bit. Voltage measurements equal to or below this threshold will clear its alarm or warning bit.

Lower Memory, Register 30h to 5Fh: PW2 EE

FACTORY DE	FAULT:	00h						
READ ACCES	S	All						
WRITE ACCES	SS	PW2						
MEMORY TYPE:		Nonvolat	ile (EE)					
30h to 5Fh	EE	EE	EE	EE	EE	EE	EE	EE
	bit7							bit0

PW2 level access controlled EEPROM.

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Lower Memory, Register 60h to 61h: Temp Value

POWER-ON VALUE	0000h
READ ACCESS	All
WRITE ACCESS	N/A
MEMORY TYPE:	Volatile

60h	S	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
61h	2 ⁻¹	2-2	2 ⁻³	2-4	2-5	2-6	2-7	2-8
	bit7							bit0

Signed two's complement direct-to-temperature measurement.

Lower Memory, Register 62h to 63h: V_{CC} Value Lower Memory, Register 64h to 65h: MON1 Value Lower Memory, Register 66h to 67h: MON2 Value Lower Memory, Register 68h to 69h: MON3 Value Lower Memory, Register 6Ah to 6Bh: MON4 Value

POWER-ON V READ ACCES WRITE ACCES	S	0000h All N/A						
MEMORY TYP	Ϋ́Ε:	Volatile						
62, 64, 66, 68, 6Ah	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸
63, 65, 67, 69, 6Bh	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

Left-justified unsigned voltage measurement.

Lower Memory, Register 6Ch to 6D: Reserved

POWER-ON V	'ALUE	00h		
READ ACCES	S	All		
WRITE ACCES	SS	N/A		
MEMORY TYP	PE:			
6C 6Dh	0	0	0	

6C, 6Dh	0	0	0	0	00	0	0	0
	bit7							bit0

These registers are reserved. The value when read is 00h.

Lower Memor	ry, Register 6	Eh: Status								
POWER-ON V	ALUE	x000 0x0)x b							
READ ACCES	S	All	All							
WRITE ACCES	SS	See Belo	W							
MEMORY TYP	E:	Volatile								
Write Access	N/A	ALL	N/A	ALL	ALL	N/A	N/A	N/A		
6Eh	FETG STATUS	SOFT FETG	RESERVED	TX-F RESET	SOFT TX-D	TX-F STATUS	LOS STATUS	RDYB		
	bit7						· · · · ·	bit0		
	1.17		S: Reflects the plarity of FETG.	active state of	FETG. The FET	G-DIR bit in Ta	ble 02h, Regist	er 89h		
	bit7		peration. Bias a	nd modulation (outputs are ena	abled.				
		1 = The FETG	output is active	e. Bias and mo	dulation output	s are disabled.				
		SOFT FETG:								

bit6	SOFT FETG: 0 = (Default)					
	1 = Forces the bias and modulation outputs to their off states and asserts the FETG output.					
bit5	RESERVED (Default = 0)					
	TX-F RESET:					
bit4	0 = Does not affect the TX-F output. (Default)					
	1 = Resets the latch for the TX-F output. This bit is self-clearing after the reset.					
	SOFT TX-D: This bit allows a software control is identical to the TX-D pin. See the section on TX-D for further information. Its value is wired-ORed with the logic value of the TX-D pin.					
bit3	0 = Internal TX-D signal is equal to external TX-D pin.					
	1 = Internal TX-D signal is high.					
	TX-F STATUS: Reflects the active state of TX-F.					
bit2	0 = TX-F pin is not active.					
	1 = TX-F pin is active.					
bit1	 LOS STATUS: Loss of Signal. Reflects the logic level of the D0 input pin. Note that with the use of the MUX LOSI and INV LOSI bits (Table 02h, Register C0h), the D0 pin is controlled by the LOSI pin. 0 = D0 is logic-low. 1 = D0 is logic-high. 					
	RDYB: Ready Bar.					
bit0	$0 = V_{CC}$ is above POA.					
	$1 = V_{CC}$ is below POA or too low to communicate over the I ² C bus.					

Lower Memory, Register 6Fh: Update

POWER-ON V	ALUE	00h	00h			
READ ACCES	S	All	All			
WRITE ACCES	SS	All + DS	All + DS1865 Hardware			
MEMORY TYP	E:	Volatile				
6Fh	TEMP RDY	V _{CC} RDY	MON1 RDY	MON2 RDY		
-	bit7					

2...

Update of completed conversions. At power-on, these bits are cleared and are set as each conversion is completed. These bits can be cleared so that a completion of a new conversion is verified.

MON3 RDY

MON4 RDY

RESERVED

RESERVED

bit0

Lower Memo	ry, Register 7	0h: Alarm ₃						
POWER-ON V	ALUE	10h						
READ ACCESS		All						
WRITE ACCES	SS	N/A						
MEMORY TYP	E:	Volatile						
70h	TEMP HI	TEMP LO	V _{CC} HI	V _{CC} LO	MON1 HI	MON1 LO	MON2 HI	MON2 LO
	bit7							bit0
	bit7	0 = (Default) L	ast measurem	for Temperatur ent was equal to bove threshold	o or below thre			
	bit6	0 = (Default) L	ast measurem	for Temperatur ent was equal to elow threshold	o or above thre			
	bit5	0 = (Default) L	ast measurem	r V _{CC} Measure ent was equal t bove threshold	o or below thre	shold setting.		
bit4 Vcc LO: Low Alarm Status for V _{CC} Measurement. This bit is set when the V _{CC} supply is b POA trip point value. It will clear itself when a V _{CC} measurement is completed and the value the low threshold. 0 = Last measurement was equal to or above threshold setting. 1 = (Default) Last measurement was below threshold setting.					is below the alue is above			
 MON1 HI: High Alarm Status for MON1 Measurement. 0 = (Default) Last measurement was equal to or below threshold setting. 1 = Last measurement was above threshold setting. 								
MON1 LO: Low Alarm Status for MON1 Measurement. bit2 0 = (Default) Last measurement was equal to or above threshold setting. 1 = Last measurement was below threshold setting.								
	bit1	0 = (Default) L	ast measurem	for MON2 Mea ent was equal to bove threshold	o or below thre	shold setting.		
	bit0	0 = (Default) L	ast measurem	for MON2 Mea ent was equal to elow threshold	o or above thre	shold setting.		

Lower Memory, Register 71h: Alarm₂

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	N/A
MEMORY TYPE:	Volatile

71h	MON3 HI	MON3 LO	MON4 HI	MON4 LO	RESERVED	RESERVED	RESERVED	RESERVED
	bit7							bit0

bit7	 MON3 HI: High Alarm Status for MON3 Measurement. 0 = (Default) Last measurement was equal to or below threshold setting. 1 = Last measurement was above threshold setting. 				
bit6 MON3 LO: Low Alarm Status for MON3 Measurement. 0 = (Default) Last measurement was equal to or above threshold setting. 1 = Last measurement was below threshold setting.					
bit5	 MON4 HI: High Alarm Status for MON4 Measurement. 0 = (Default) Last measurement was equal to or below threshold setting. 1 = Last measurement was above threshold setting. 				
bit4	bit4 MON4 LO: Low Alarm Status for MON4 Measurement. 0 = (Default) Last measurement was equal to or above threshold setting. 1 = Last measurement was below threshold setting.				
bit3:0	RESERVED				

Lower Memory, Register 72h: Alarm1

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	N/A
MEMORY TYPE:	Volatile

72h	RESERVED	RESERVED	RESERVED	RESERVED	BIAS HI	RESERVED	TXP HI	TXP LO
	bit7							bit0

bit7:4	RESERVED					
	BIAS HI: High Alarm Status Bias; Fast Comparison.					
bit3	0 = (Default) Last comparison was below threshold setting.					
	1 = Last comparison was above threshold setting.					
bit2	RESERVED					
	TXP HI: High Alarm Status TX-P; Fast Comparison.					
bit1	0 = (Default) Last comparison was below threshold setting.					
	1 = Last comparison was above threshold setting.					
	TXP LO: Low Alarm Status TX-P; Fast Comparison.					
bit0	0 = (Default) Last comparison was above threshold setting.					
	1 = Last comparison was below threshold setting.					

Lower Memory, Register 73h: Alarm ₀								
POWER-ON V	ALUE	00h						
READ ACCES	S	All						
WRITE ACCES	SS	N/A						
MEMORY TYP	PE:	Volatile						
73h	RESERVED	RESERVED	RESERVED	RESERVED	BIAS MAX	RESERVED	RESERVED	RESERVED
	bit7							bit0
	bit7:4							
	DIL7.4	RESERVED						
	BIAS MAX: Alarm Status for Maximum Digital Setting of IBIAS.							
bit3 $0 = (Default)$ The value for I _{BIAS} is equal to or below the MAX IBIAS setting.								
1 = Requested value for I _{BIAS} is greater than the MAX IBIAS setting.								
	bit2:0	RESERVED						



Lower Memory, Register 74h: Warn3

POWER-ON VALUE	10h
READ ACCESS	All
WRITE ACCESS	N/A
MEMORY TYPE:	Volatile

	0		0					
74h	TEMP HI	TEMP LO	V _{CC} HI	V _{CC} LO	MON1 HI	MON1 LO	MON2 HI	MON2 LO
	bit7							bit0

	TEMP HI: High Warning Status for Temperature Measurement.						
bit7	0 = (Default) Last measurement was equal to or below threshold setting.						
	1 = Last measurement was above threshold setting.						
	TEMP LO: Low Warning Status for Temperature Measurement.						
bit6	0 = (Default) Last measurement was equal to or above threshold setting.						
	1 = Last measurement was below threshold setting.						
	Vcc HI: High Warning Status for VCC Measurement.						
bit5	0 = (Default) Last measurement was equal to or below threshold setting.						
	1 = Last measurement was above threshold setting.						
bit4	V_{CC} LO: Low Warning Status for V _{CC} Measurement. This bit is set when the V _{CC} supply is below the POA trip point value. It will clear itself when a V _{CC} measurement is completed and the value is above the low threshold.						
	0 = Last measurement was equal to or above threshold setting.						
	1 = (Default) Last measurement was below threshold setting.						
	MON1 HI: High Warning Status for MON1 Measurement.						
bit3	0 = (Default) Last measurement was equal to or below threshold setting.						
	1 = Last measurement was above threshold setting.						
	MON1 LO: Low Warning Status for MON1 Measurement.						
bit2	0 = (Default) Last measurement was equal to or above threshold setting.						
	1 = Last measurement was below threshold setting.						
	MON2 HI: High Warning Status for MON2 Measurement.						
bit1	0 = (Default) Last measurement was equal to or below threshold setting.						
	1 = Last measurement was above threshold setting.						
	MON2 LO: Low Warning Status for MON2 Measurement.						
bit0	0 = (Default) Last measurement was equal to or above threshold setting.						
	1 = Last measurement was below threshold setting.						

Lower Memo	ry, Register 7	5h: Warn ₂									
POWER-ON V	ALUE	00h									
READ ACCES	S	All									
WRITE ACCES	SS	N/A									
MEMORY TYP	E:	Volatile									
75h	MON3 HI	MON3 LO	MON4 HI	MON4 LO	RESERVED	RESERVED	RESERVED	RESERVED			
	bit7							bit0			
	bit7		ast measurem		o or below thre	shold setting.					
	bit6	, ,	ast measurem		o or above thre	shold setting.					
	bit5		ast measurem		o or below thre	shold setting.					
bit4 MON4 LO: Low Warning Status for MON4 Measurement. 0 = (Default) Last measurement was equal to or above threshold setting. 1 = Last measurement was below threshold setting.											
bit3:0 RESERVED											
Lower Memor	ry, Register 7	6h to 77h: Rese	erved								
POWER-ON VALUE		00h									
READ ACCES	S	All	All								
WRITE ACCESS N/A											

MEMORY TYPE:

76, 77h	0	0	0	0	00	0	0	0
	bit7							bit0

These registers are reserved. The value when read is 00h.

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Lower Memory, Register 78h: DOUT

POWER-ON V		Recalled	Recalled from Table 02h, Register C0h					
READ ACCES	-	All	, O					
WRITE ACCES	-	All						
MEMORY TYP	'E:	Volatile						
78h	RESERVED	RESERVED	RESERVED	RESERVED	D			

bit7

D3 OUT D2 OUT D1 OUT D0 OUT

bit0

bit0

At power-on, these bits are defined by the value stored in the DPU byte (Table 02h, Register C0h). These bits define the value of the logic states of their corresponding output pins.

Lower Memory, Register 79h: DIN

POWER-ON V	ALUE	See desc	ription					
READ ACCES	S	All						
WRITE ACCES	SS	N/A						
MEMORY TYP	E:	Volatile						
79h	RESERVED	RESERVED	INV LOSI	MUX LOSI	D3 IN	D2 IN	D1 IN	D0 IN

bit7

bit7:6	RESERVED
bit5	 INV LOSI: Allows for inversion of LOSI pin to D0 pin. MUX LOSI bit must be set to 1 or this bit does not affect the output. This bit is controlled (or set) by the DPU byte (Table 02h, Register C0h). 1 = LOS buffered OUT₀ is inverted.
	MUX LOSI: Determines control of D0 pin. This bit is controlled (or set) by the DPU byte (Table 02h, Register C0h).
bit4	0 = Logic value of D0 is controlled by DOUT byte.
	1 = Logic value of D0 is controlled by LOSI pin and INV LOSI bit.
bit3	D3 IN: Reflects the logic value of D3 pin.
bit2	D2 IN: Reflects the logic value of D2 pin.
bit1	D1 IN: Reflects the logic value of D1 pin.
bit0	D0 IN: Reflects the logic value of D0 pin.

Lower Memory, Register 7Ah: Reserved

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	N/A

MEMORY TYPE:

7Ah	0	0	0	0	00	0	0	0
	bit7							bit0

This register is reserved. The value when read is 00h.

Lower Memory, Register 7Bh to 7Eh: Password Entry (PWE)

POWER-ON VALUE	FFFF FFFFh
READ ACCESS	N/A
WRITE ACCESS	All
MEMORY TYPE:	Volatile

7Bh	2 ³¹	2 ³⁰	2 ²⁹	2 ²⁸	2 ²⁷	2 ²⁶	2 ²⁵	2 ²⁴
7Ch	2 ²³	2 ²²	2 ²¹	2 ²⁰	2 ¹⁹	2 ¹⁸	2 ¹⁷	2 ¹⁶
7Dh	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸
7Eh	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

Password Entry. There are two passwords for the DS1865. Each password is 4 bytes long. The lower level password (PW1) will have access to all unprotected areas plus those made available with PW1. The higher level password (PW2) will have all the access of PW1 plus those made available with PW2. The values of the passwords reside in EEPROM inside of PW2 memory. At power-up, all PWE bits are set to 1. All reads at this location are 0.

Lower Memory, Register 7Fh: Table Select (TBL SEL)

POWER-ON VALUE	00h						
READ ACCESS	All						
WRITE ACCESS	All						
MEMORY TYPE	Volatile						
7Fh 2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
bit7							bit0

The upper memory tables (Table 01h–06h) of the DS1865 are accessible by writing the desired table value in this register.

Table 01h Register Descriptions

Table 01h, Register 80h to F7h: PW1 EEPROM POWER-ON VALUE 00h **READ ACCESS** PW1 WRITE ACCESS PW1 MEMORY TYPE Nonvolatile (EE) 80h-F7h ΕE ΕE ΕE ΕE ΕE ΕE ΕE ΕE bit7 bit0 EEPROM for PW1 level access. Table 01h, Register F8h: Alarm₃ POWER-ON VALUE 00h **READ ACCESS** All WRITE ACCESS PW1 MEMORY TYPE: Volatile TEMP HI F8h V_CC LO TEMP LO V_CC HI MON1 HI MON1 LO MON2 HI MON2 LO bit7 bit0 Layout is identical to Alarm₃ in Lower Memory, Register 70h with two exceptions. 1. V_{CC} low alarm is not set at power-on. 2. These bits are latched. They are cleared by power-down or a write with PW1 access. Table 01h, Register F9h: Alarm₂ **POWER-ON VALUE** 00h **READ ACCESS** All WRITE ACCESS PW1

MEMORY TYPE:

F9h	MON3 HI	MON3 LO	MON4 HI	MON4 LO	RESERVED	RESERVED	RESERVED	RESERVED
	bit7							bit0

Layout is identical to Alarm₂ in Lower Memory, Register 71h with one exception.

Volatile

1. These bits are latched. They are cleared by power-down or a write with PW1 access.

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Table 01h, Register FAh: Alarm ₁										
POWER-ON VALUE		00h								
READ ACCESS		All								
WRITE ACCESS		PW1								
MEMORY TYPE:		Volatile								
FAh	RESERVED	RESERVED	RESERVED	BIAS HI	RESERVED	RESERVED	TXP HI	TXP LO		
	bit7							bit0		

Layout is identical to Alarm1 in Lower Memory, Register 72h with one exception.

1. These bits are latched. They are cleared by power-down or a write with PW1 access.

Table 01h, Register FBh: Alarm0

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	PW1
MEMORY TYPE:	Volatile

FBh	RESERVED	RESERVED	RESERVED	RESERVED	BIAS MAX	RESERVED	RESERVED	RESERVED
	bit7							bit0

Layout is identical to Alarmo in Lower Memory, Register 73h with one exception.

1. These bits are latched. They are cleared by power-down or a write with PW1 access.

Table 01h, Register FCh: Warn₃

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	PW1
MEMORY TYPE:	Volatile

FCh	TEMP HI	TEMP LO	V _{CC} HI	V _{CC} LO	MON1 HI	MON1 LO	MON2 HI	MON2 LO
-	bit7							bit0

Layout is identical to Warn₃ in Lower Memory, Register 74h with two exceptions.

1. V_{CC} Low Warning is not set at power-on.

2. These bits are latched. They are cleared by power-down or a write with PW1 access.

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Table 01h, Register FDh: Warn₂

POWER-ON VALUE	00h						
READ ACCESS	All						
WRITE ACCESS	PW1						
MEMORY TYPE:	Volatile						
FDh MON3 HI	MON3 LO	MON4 HI	MON4 LO	RESERVED	RESERVED	RESERVED	RESERVED
bit7							bit0

Layout is identical to Warn₂ in Lower Memory, Register 75h with one exception.

1. These bits are latched. They are cleared by power-down or a write with PW1 access.

Table 01h, Register FEh to FFh: Reserved

POWER-ON VALUE	00h
READ ACCESS	All
WRITE ACCESS	PW1
MEMORY TYPE:	Volatile

These registers are reserved.

_Table 02h Register Descriptions

Table 02h, Re	gister 80h: N	lode								
POWER-ON V	ALUE	1Fh								
READ ACCES	S	PW2								
WRITE ACCES	S	PW2								
MEMORY TYP	E:	Volatile								
80h	SEEB	RESERVED	RESERVED	M4DAC-EN	AEN	MOD-EN	APC-EN	BIAS-EN		
=	bit7							bit0		
Г		0550								
		SEEB:	nables EEDDO	M writes to SEE	butos					
	bit7	, ,	 0 = (Default) Enables EEPROM writes to SEE bytes. 1 = Disables EEPROM writes to SEE bytes during configuration, so that the configuration of the part is 							
		not delayed by locations again	y the EE cycle	time. Once the	e values are kr					
	bit6:5	RESERVED								
		M4DAC-EN:								
bit4 0 = M4DAC is writeable by the user and the LUT recalls are disabled. This allows uniteractively test their modules by writing the DAC value for M4DAC. The output is updated new value at the end of the write cycle. The I ² C STOP condition is the end of the write cycle.							dated with the			
1 = (Default) Enables auto control of the LUT for M4DAC.										
AEN:										
 bit3 bit3 bit3 calculated indexes are disabled. This allows users to interactively test their mod indexing for the lookup tables. The recalled values from the LUTs will appear after the next completion of a temperature conversion (just like it would happe DACs will update at the same time (just like in auto mode). 					eir modules by appear in the	controlling the DAC registers				
-		1 = (Default) E	naples auto co	Introl of the LU						
		MOD-EN: 0 = MOD DAC is writeable by the user and the LUT recalls are disabled. This allows users to								
	bit2	interactively te	st their modul	les by writing the DAC value for modulation. The output is updated with ne write cycle. The I^2C STOP condition is the end of the write cycle.						
		1 = (Default) E	nables auto co	ntrol of the LUT	for modulatior	٦.				
		APC-EN:								
	bit1	0 = APC DAC interactively te with the new va	est their modul	es by writing t	he DAC value	for APC refere	ence. The outp	out is updated		
		1 = (Default) E	nables auto co	ntrol of the LUT	for APC refere	ence.				
		BIAS-EN:								
	bitO	0 = BIAS DAC is controlled by the user and the APC is open loop. The BIAS DAC value is written to the MAN IBIAS register. All values that are written to MAN IBIAS and are greater than the MAX IBIAS register setting are not updated and will set the BIAS MAX alarm bit. The BIAS DAC register will continue to reflect the value of the BIAS DAC. This allows users to interactively test their modules by writing the DAC value for I _{BIAS} . The output is updated with the new value at the end of the write cycle to the MAN IBIAS register. The I ² C STOP condition is the end of the write cycle.								
		1 = (Default) E	nables auto co	ntrol for the AP	C feedback.					

Table 02h, Register 81h: Tindex

POWER-ON VAL	UE	00h	00h						
READ ACCESS		PW2	PW2						
WRITE ACCESS		PW2 and	PW2 and (AEN = 0)						
MEMORY TYPE		Volatile	Volatile						
81h	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰	
	bit7							bit0	

Holds the calculated index based on the Temperature Measurement. This index is used for the address during lookup of tables 04h and 05h. Temperature measurements below -40°C or above 102°C are clamped to 00h and C7h, respectively. The calculation of Tindex is as follows:

$$Tindex = \frac{Temp + 40^{\circ}C}{2^{\circ}C} + 80h$$

For the two temperature-indexed LUTs, the index used during the lookup function for each table is as follows:

Table 04h MOD	1	Tindex ₆	$Tindex_{5}$	Tindex ₄	Tindex ₃	Tindex ₂	Tindex ₁	Tindex ₀
Table 05h APC	1	0	Tindex ₆	Tindex₅	Tindex₄	Tindex ₃	Tindex ₂	Tindex,

Table 02h, Register 82h: MOD DAC

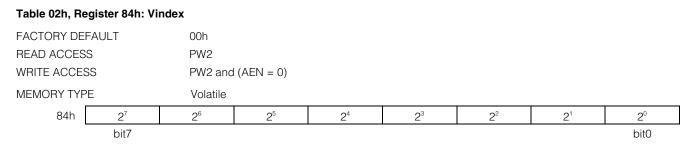
POWER-ON V	ALUE	00h	00h					
READ ACCES	S	PW2	PW2					
WRITE ACCES	S	PW2 and	PW2 and (MOD-EN = 0)					
MEMORY TYP	E	Volatile						
82h	27	2 ⁶	2^{6} 2^{5} 2^{4} 2^{3} 2^{2} 2^{1} 2^{0}					
-	bit7							bit0

The digital value used for MOD and recalled from Table 04h at the adjusted memory address is found in Tindex. (R.O.) This register is updated at the end of every temperature conversion.

Table 02h, Register 83h: APC DAC

POWER-ON VALUE		00h	00h					
READ ACCESS		PW2	PW2					
WRITE ACCESS		PW2 and	PW2 and $(APC-EN = 0)$					
MEMORY TYPE		Volatile						
83h 2	7	2 ⁶	2^{6} 2^{5} 2^{4} 2^{3} 2^{2} 2^{1} 2^{0}					
bit	:7							bit0

The digital value used for APC reference and recalled from Table 05h at the adjusted memory address found in Tindex. (R.O.) This register is updated at the end of the temperature conversion.



Holds the calculated index based on the MON4 voltage measurement. This index is used for the address during lookup of Table 06h. M4DAC LUT (Table 06h) is 32 bytes from address 80h to 9Fh. The calculation of Vindex is as follows:

$Vindex = \frac{Mon4}{800h} + 80h$

When configured as a single LUT, all 32 bytes are used for lookup.

When configured as a double LUT, the first 16 bytes (80h-8Fh) form the lower LUT and the last 16 bytes (90h-9Fh) form the upper LUT. For the three different modes, the index used during the lookup function of Table 06h is as follows:

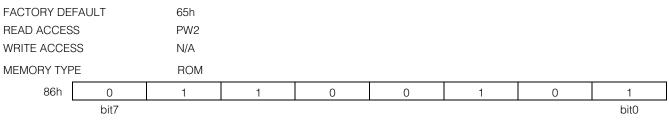
Single	1	0	0	Vindex ₄	Vindex ₃	Vindex ₂	Vindex ₁	Vindex ₀
Double / Lower	1	0	0	0	Vindex ₄	Vindex ₃	Vindex ₂	Vindex ₁
Double / Upper	1	0	0	1	Vindex ₄	Vindex ₃	Vindex ₂	Vindex ₁

Table 02h, Register 85h: M4DAC

FACTORY DEFAULT	00 00h	00 00h					
READ ACCESS	PW2	PW2					
WRITE ACCESS	PW2 and	PW2 and $(M4DAC-EN = 0)$					
MEMORY TYPE:	Volatile						
85h 2 ⁷	2 ⁶	2^{6} 2^{5} 2^{4} 2^{3} 2^{2} 2^{1} 2^{0}					
bit7							bit0

The digital value used for M4DAC and recalled from Table 06h at the adjusted memory address is found in Vindex. (R.O.) This register is updated at the end of the MON4 conversion.

Table 02h, Register 86h: Device ID



Hardwired connections to show device ID.

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Table 02h, Register 87h: Device VER

FACTORY DEFAULT	Device Version
READ ACCESS	PW2
WRITE ACCESS	N/A
MEMORY TYPE	ROM
87h	DEVICE VERSION
bit7	

Hardwired connections to show device version.

Table 02h, Register 88h: Update Rate

FACTORY DEFAULT	00h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE	Nonvolatile (SEE)

Defines the update rate for comparison of APC control.

88h	0	0	0	0	SR_3	SR_2	SR_1	SR_0
	bit7							bit0

bit7:4	0:
bit3:0	SR(3:0): 4-bit sample rate for comparison of APC control.

BIT SR ₃ -SR ₀	MINIMUM TIME FROM BEN TO FIRST SAMPLE (t _{FIRST}) ±50ns	REPEATED SAMPLE PERIOD FOLLOWING FIRST SAMPLE (t _{REP})
d0000	350ns	800ns
0001b	550ns	1200ns
0010b	750ns	1600ns
0011b	950ns	2000ns
0100b	1350ns	2800ns
0101b	1550ns	3200ns
0110b	1750ns	3600ns
0111b	2150ns	4400ns
1000b	2950ns	6000ns
*1001b	3150ns	6400ns

*All codes greater than 1001b (1010b–1111b) use the maximum sample time of code 1001b.

bit0

Table 02h, Register 89h: Config								
FACTORY DE	FAULT	00h						
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	E:	Nonvola	tile (SEE)					
89h	FETG DIR	TX-F EN	RESERVED	ASEL	RESERVED	RESERVED	RESERVED	RESERVED
	bit7							bit0

Configure the memory location and the polarity of the digital outputs.

bit7	FETG DIR: Chooses the direction or polarity of the FETG output for normal operation. 0 = (Default) Under normal operation, FETG is pulled low. Intended for use with nMOS. 1 = Under normal operation, FETG is pulled high. Intended for use with pMOS.
	TX-F EN: The TX-F output pin always reflects the wired-OR of all TXF enabled alarm states. This bit will enable the latching of the alarm state for the TXF output pin.
bit6	0 = (Default) Not latched.
Dito	1 = The alarm bits are latched until cleared by a TX-D transition or power-down. If V _{CC} _Lo_Alarm is enabled for either FETG or TX-F then latching is disabled until the after the first V _{CC} measurement is made above the V _{CC} _Lo set point to allow for proper operation during slow power-on cycles.
bit5	RESERVED
	ASEL: Address Select.
bit4	0 = (Default) Device Address of A2h.
5114	$1 = I^2C$ slave address is determined by the value programmed in the DEVICE ADDRESS byte (Table 02h, Register 8Ch).
bit3:0	RESERVED

Table 02h, Register 8Ah: Startup Step

FACTORY DEF	AULT:	00h						
READ ACCESS		PW2	PW2					
WRITE ACCES	S	PW2						
MEMORY TYPE	Ξ:	Nonvolat	ile (SEE)					
8Ah	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	27	2 ⁶	2 ⁵
_	bit7							bit0

This value will define the maximum allowed step for the upper 8 bits of I_{BIAS} output during startup. Programming this value to 00h cause the device to take single LSB (2°) steps towards convergence. See the *BIAS and MOD Output During Power-Up* section for details.

Table 02h, Register 8Bh: MOD Ranging

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FACTORY DE	FAULT:	00h	
READ ACCES	S	PW2	
WRITE ACCES	SS	PW2	
MEMORY TYP	PE:	Nonvolat	ile (SEE)
8Bh	RESERVED	RESERVED	RESER

RESERVED

bit7

MOD ₂	MOD ₁

MOD

bit0

The lower nibble of this byte controls the full-scale range of the modulation DAC.

bit7:3	RESERVED (Default = 0)
bit2:0	MOD₂, MOD₁, MOD₆: MOD FS Ranging. 3-bit value to select the FS output voltage for VMOD. Default is 000b and creates a FS of 1.25V.

RESERVED

$MOD_2 - MOD_0$	% OF 1.25V	FS VOLTAGE (V)
000b	100.00	1.250
001b	80.05	1.001
010b	66.75	0.833
011b	50.13	0.627
100b	40.16	0.502
101b	33.50	0.419
110b	28.75	0.359
111b	25.18	0.315

RESERVED

Table 02h, Register 8Ch: Device Address

FACTORY DEFA	ULT:	00h						
READ ACCESS		PW2						
WRITE ACCESS		PW2						
MEMORY TYPE:		Nonvolat	ile (SEE)					
8Ch	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

This value becomes the I²C slave address for the main memory when the ASEL bit (Table 02h, Register 89h) is set.

Table 02h, Register 8Dh: Comp Ranging FACTORY DEFAULT: 00h READ ACCESS PW2 PW2 WRITE ACCESS MEMORY TYPE: Nonvolatile (SEE) 8Dh RESERVED BIAS₂ BIAS₀ RESERVED APC₂ APC BIAS₁ APC₀ bit7

bit0

The upper nibble of this byte controls the Full-Scale range of the Quick-Trip monitoring for BIAS. The Lower nibble of this byte controls the Full-Scale range for the Quick-Trip monitoring of the APC reference as well as the closed loop monitoring of APC.

bit7	RESERVED (Default = 0)
bit6.4	BIAS₂, BIAS₁, BIAS₀: BIAS FS Ranging: 3-bit value to select the FS comparison voltage for BIAS found on MON1. Default is 000b and creates an FS of 1.25V.
bit3	RESERVED (Default = 0)
bit2:0	APC₂, APC₁, APC₀: APC FS Ranging: 3-bit value to select the FS comparison voltage for BMD with the APC. Default is 000b and creates an FS of 2.5V.

BIAS ₂ – BIAS ₀	% OF 1.25V	FS VOLTAGE (V)
000b	100.00	1.250
001b	80.10	1.001
010b	66.83	0.835
011b	50.25	0.628
100b	40.30	0.504
101b	33.66	0.421
110b	28.92	0.362
111b	25.39	0.317

APC ₂ – APC ₀	% OF 2.50V	FS VOLTAGE (V)
000b	100.00	1.250
001b	80.10	1.001
010b	66.83	0.835
011b	50.25	0.628
100b	40.30	0.504
101b	33.66	0.421
110b	28.92	0.362
111b	25.39	0.317

Table 02h, Register 8Eh: Right Shift1 (RSHIFT1)

FACTORY DE	FAULT:	00h						
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	PE:	Nonvolat	ile (SEE)					
8Eh	RESERVED	MON1 ₂	MON1 ₁	MON1 ₀	RESERVED	MON ₂	MON2 ₁	MON2 ₀
	bit7							bit0

Allows for right-shifting the final answer of MON1 and MON2 voltage measurements. This allows for scaling the measurements to the smallest full-scale voltage and then right-shifting the final result so the reading is weighted to the correct LSB. See the *Right Shifting ADC Results* section for details.

Table 02h, Register 8Fh: Right Shift₀ (RSHIFT₀)

FACTORY DEFAULT:	00h						
READ ACCESS	PW2						
WRITE ACCESS	PW2						
MEMORY TYPE:	Nonvolat	ile (SEE)					
8Fh RESERVED	MON3 ₂	MON3 ₁	MON3 ₀	RESERVED	MON4 ₂	MON4 ₁	MON4 ₀
bit7							bit0

Allows for right-shifting the final answer of MON3 and MON4 voltage measurements. This allows for scaling the measurements to the smallest full-scale voltage and then right-shifting the final result so the reading is weighted to the correct LSB. See the *Right Shifting ADC Results* section for details.

Table 02h, Register 90h to 91h: Reserved

FACTORY DEFAULT:	0000h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)
These registers are reserved.	

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Table 02h, Register 92h to 93h: V_{CC} Scale Table 02h, Register 94h to 95h: MON1 Scale Table 02h, Register 96h to 97h: MON2 Scale Table 02h, Register 98h to 99h: MON3 Scale Table 02h, Register 9Ah to 9Bh: MON4 Scale

FACTORY CA	LIBRATED							
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	PE:	Nonvolat	tile (SEE)					
92, 94, 96, 98, 9Ah	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸
93, 95, 97, 99, 9Bh	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2º

bit7

bit0

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Controls the scaling or gain of the FS voltage measurements. The factory-calibrated value produces an FS voltage of 6.5536V for V_{CC} and 2.5V for MON1, MON2, MON3, and MON4.

Table 02h, Register 9Ch to A1h: Reserved

FACTORY DEFAULT:	0000h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)

These registers are reserved.

Table 02h, Register A2h to A3h: V_{CC} Offset Table 02h, Register A4h to A5h: MON1 Offset Table 02h, Register A6h to A7h: MON2 Offset Table 02h, Register A8h to A9h: MON3 Offset Table 02h, Register AAh to ABh: MON4 Offset

FACTORY DEFAULT:	0000h
READ ACCESS	PW2
WRITE ACCESS	PW2

MEMORY TYPE: Nonvolatile (SEE)

A2, A4, A6, A8, AAh	S	S	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰
A3, A5, A7, A9, ABh	2°	2 ⁸	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²
	bit7							bit0

Allows for offset control of these voltage measurements if desired.

Table 02h, Register ACh to ADh: Reserved

FACTORY DEFAULT:	0000 0000h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)

These registers are reserved.

Table 02h, Register AEh to AFh: Internal Temp Offset

FACTORY CALIBRATED	
READ ACCESS	PW2
WRITE ACCESS	PW2

MEMORY TYPE

Nonvolatile (SEE)

Nonvolatile (SEE)

AEh	S	2 ⁸	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²
AFh	2 ¹	2°	2 ⁻¹	2-2	2-3	2-4	2 ⁻⁵	2-6
	bit7							bit0

Allows for offset control of the temperature measurement if desired. The final result must be XORed with BB40h before writing to this register. Factory calibration contains the desired value for a reading in degrees Celsius.

Table 02h, Register B0h to B3h: PW1

FF FFFFh
/Α
W2

MEMORY TYPE

			. ,					
B0h	2 ³¹	2 ³⁰	2 ²⁹	2 ²⁸	2 ²⁷	2 ²⁶	2 ²⁵	2 ²⁴
B1h	2 ²³	2 ²²	2 ²¹	2 ²⁰	2 ¹⁹	2 ¹⁸	2 ¹⁷	2 ¹⁶
B2h	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸
B3h	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

The PWE value is compared against the value written to this location to enable PW1 access. At power-on, the PWE value is set to all ones. Thus, writing these bytes to all ones grants PW1 access on power-up without writing the password entry. All reads of this register are 00h.

Table 02h, Re	gister B4h to	B7h: PW2						
FACTORY DEF	AULT	FFFF FFF	Fh					
READ ACCESS	5	N/A						
WRITE ACCES	S	PW2						
MEMORY TYPI	E	Nonvolat	ile (SEE)					
B4h	2 ³¹	2 ³⁰	2 ²⁹	2 ²⁸	2 ²⁷	2 ²⁶	2 ²⁵	2 ²⁴
B5h	2 ²³	2 ²²	2 ²¹	2 ²⁰	2 ¹⁹	2 ¹⁸	2 ¹⁷	2 ¹⁶
B6h	2 ¹⁵	2 ¹⁴	2 ¹³	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸
B7h	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
	bit7							bit0

The PWE value is compared against the value written to this location to enable PW2 access. At power-on, the PWE value is set to all ones. Thus, writing these bytes to all ones grants PW2 access on power-up without writing the password entry. All reads of this register are 00h.

Table 02h, Register B8h: FETG Enable1 (FETG EN1)

FACTORY DEFAULT	00h						
READ ACCESS	PW2						
WRITE ACCESS	PW2						
MEMORY TYPE:	Nonvola	tile (SEE)					
B8h TEMP EN	V _{CC} EN	MON1 EN	MON2 EN	MON3 EN	MON4 EN	RESERVED	RESERVED
bit7							bit0

Configures the maskable interrupt for the FETG pin.

	 0 = Disable (Default). 1 = Enable. MON3 EN: Enables/disables active interrupts on the FETG pin due to MON3 measurements outside the threshold limits.
bit4	MON2 EN: Enables/disables active interrupts on the FETG pin due to MON2 measurements outside the threshold limits. 0 = Disable (Default).
bit5	 MON1 EN: Enables/disables active interrupts on the FETG pin due to MON1 measurements outside the threshold limits. 0 = Disable (Default). 1 = Enable.
bit6	 V_{CC} EN: Enables/disables active interrupts on the FETG pin due to V_{CC} measurements outside the threshold limits. 0 = Disable (Default). 1 = Enable.
bit7	 TEMP EN: Enables/disables active interrupts on the FETG pin due to temperature measurements outside the threshold limits. 0 = Disable (Default). 1 = Enable.

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Table 02h, Register B9h: FETG Enable₀ (FETG EN₀)

FACTORY DEF	AULT	00h						
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	E:	Nonvolat	tile (SEE)					
B9h	HTXP EN	LTXP EN	BIAS-HI EN	BIAS MAX EN	RESERVED	RESERVED	RESERVED	RESERVED
	bit7							bit0

Configures the maskable interrupt for the FETG pin.

bit7	HTXP EN: Enables/disables active interrupts on the FETG pin due to TXP fast comparisons above the threshold limit.0 = Disable (Default).
	1 = Enable.
bit6	LTXP EN: Enables/disables active interrupts on the FETG pin due to TXP fast comparisons below the threshold limit. 0 = Disable (Default).
	1 = Enable.
bit5	BIAS HI EN: Enables/disables active interrupts on the FETG pin due to BIAS fast comparisons above the threshold limit.
DILO	0 = (Default) Disable.
	1 = Enable.
	BIAS MAX EN: Enables/disables active interrupts on the FETG pin due to BIAS fast comparisons below the threshold limit.
bit4	0 = (Default) Disable.
	1 = Enable.
bit3:0	RESERVED (Default = 0)

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Table 02h, Register BAh: TX-F Enable1 (TX-F EN1)

FACTORY DE	FAULT	00h						
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	'E:	Nonvolat	tile (SEE)					
BAh	TEMP EN	V _{CC} EN	MON1 EN	MON2 EN	MON3 EN	MON4 EN	RESERVED	RESERVED
	bit7							bit0

Configures the maskable interrupt for the TX-F pin.

	TEMP EN: Enables/disables active interrupts on the TX-F pin due to temperature measurements outside the threshold limits.
bit7	0 = Disable (Default).
	1 = Enable.
bit6	V_{CC} EN: Enables/disables active interrupts on the TX-F pin due to V _{CC} measurements outside the threshold limits.
	0 = Disable (Default).
	1 = Enable.
	MON1 EN: Enables/disables active interrupts on the TX-F pin due to MON1measurements outside the threshold limits.
bit5	0 = Disable (Default).
	1 = Enable.
	MON2 EN: Enables/disables active interrupts on the TX-F pin due to MON2 measurements outside the threshold limits.
bit4	0 = Disable (Default).
	1 = Enable.
	MON3 EN: Enables/disables active interrupts on the TX-F pin due to MON3 measurements outside the threshold limits.
bit3	0 = Disable (Default).
	1 = Enable.
	MON4 EN: Enables/disables active interrupts on the TX-F pin due to MON4 measurements outside the threshold limits.
bit2	0 = Disable (Default).
	1 = Enable.
bit2:0	RESERVED (Default = 0)

Table 02h, Register BBh: TX-F Enable₀ (TX-F EN₀)

FACTORY DEFAULT	00h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvo

IEMORY TYP	E:	Nonvolat	ile (SEE)					
BBh	HTXP EN	LTXP EN	BIAS-HI EN	BIAS MAX EN	RESERVED	RESERVED	RESERVED	FETG EN
	bit7							bit0

Configures the maskable interrupt for the Tx-F pin.

bit7	HTXP EN: Enables/disables active interrupts on the TX-F pin due to TXP fast comparisons above the threshold limit.
DIL7	0 = Disable (Default).
	1 = Enable.
	LTXP EN: Enables/disables active interrupts on the TX-F pin due to TXP fast comparisons below the threshold limit.
bit6	0 = Disable (Default).
	1 = Enable.
	BIAS-HI EN: Enables/disables active interrupts on the TX-F pin due to BIAS fast comparisons above the threshold limit.
bit5	0 = Disable (Default).
	1 = Enable.
	BIAS MAX EN: Enables/disables active interrupts on the TX-F pin due to BIAS fast comparisons above the threshold limit.
bit4	0 = Disable (Default).
	1 = Enable.
bit3:1	RESERVED (Default = 0)
	FETG EN:
bit0	0 = Normal FETG operation (Default).
	1 = Enables FETG to act as an input to TX-F output.

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Table 02h, Register BCh: HTXP

FACTORY DEFA	ULT:	00h						
READ ACCESS		PW2						
WRITE ACCESS		PW2						
MEMORY TYPE:		Nonvola	tile (SEE)					
BCh	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
	bit7							bit0

Fast-comparison DAC threshold adjust for high transmit power. This value is added to the APC_DAC value recalled from Table 04h. If the sum is greater than 0xFF, 0xFF is used. Comparisons greater than APC_DAC plus this value, found on the BMD pin, will create a TXP-HI alarm.

Table 02h, Register BDh: LTXP

FACTORY DE	FAULT:	00h						
READ ACCESS PW2		PW2	PW2					
WRITE ACCES	SS	PW2						
MEMORY TYP	E:	Nonvolat	tile (SEE)					
BDh	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

Fast-comparison DAC threshold adjust for low transmit power. This value is subtracted from the APC_DAC value recalled from Table 04h. If the difference is less than 0x00, 0x00 is used. Comparisons less than APC_DAC minus this value, found on the BMD pin, create a TXP-LO alarm.

Table 02h, Register BEh: HBIAS

FACTORY DEF	FAULT:	00h							
READ ACCES	S	PW2							
WRITE ACCESS		PW2	PW2						
MEMORY TYP	E:	Nonvolat	ile (SEE)						
BEh	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰	
-	bit7							bit0	

Fast-comparison DAC setting for high BIAS. Comparisons greater than this value, found on the MON1 pin, create a BIAS HI alarm.

Table 02h, Register BFh: MAX IBIAS

FACTORY DEF	AULT:	00h							
READ ACCESS	5	PW2							
WRITE ACCESS		PW2							
MEMORY TYPE	Ξ:	Nonvolat	ile (SEE)						
BFh	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	2 ⁷	2 ⁶	2 ⁵	
	bit7							bit0	

This value defines the maximum DAC value allowed for the upper 8 bits of I_{BIAS} output during all operations. During the intial step and binary search, this value will not cause an alarm but will still clamp the I_{BIAS} DAC output. After the startup seqence (or normal APC operations), if the APC loop tries to create an I_{BIAS} value greater than this setting, it is clamped and creates a BIAS MAX alarm. Settings 00h through FEh are intended for normal APC mode of operation. Setting FFh is reserved for manual IBIAS mode.

Table 02h, Re	egister C0h: D	PU						
FACTORY DE	FAULT	00h						
READ ACCES	S	PW2						
WRITE ACCES	SS	PW2						
MEMORY TYP	E:	Nonvolat	ile (SEE)					
C0h	RESERVED	RESERVED	INV LOSI	MUX LOSI	D3 CNTL	D2 CNTL	D1 CNTL	D0 CNTL
	bit7							bit0

Controls the power-on values for D3, D2, D1, and D0 output pins and mux and invertion of the LOSI pin.

Bit7:6	RESERVED
Bit5	 INV LOSI: Inverts the buffered input pin LOSI to output pin D0 if MUX LOSI is set. If MUX LOSI is not set then this bit's value is a don't care. 0 = (Default) noninverted LOSI to D0 pin. 1 = Inverted LOSI to D0 pin.
Bit4	 MUX LOSI: chooses the control for D0 output pin. 0 = (Default) DO is controlled by bit D0 OUT found in Lower Memory, Register 78h. 1 = LOSI is buffered to D0 pin.
Bit3	D3 CNTL: At power-on, this value is loaded into bit D3 OUT of Lower Memory, Register 78h to control the output pin D3.
Bit2	D2 CNTL: At power-on, this value is loaded into bit D2 OUT of Lower Memory, Register 78h to control the output pin D2.
bit1	D1 CNTL: At power-on, this value is loaded into bit D1 OUT of Lower Memory, Register 78h to control the output pin D1.
bit0	D0 CNTL: At power-on, this value is loaded into bit D0 OUT of Lower Memory, Register 78h to control the output pin D0.

Table 02h, Register C1h to C3h: Reserved

FACTORY DEFAULT:	0000 0000h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)
These registers are reserved.	

Table 02h, Register C4h: DAC1

FACTORY DEF	AULT:	00h						
READ ACCESS	6	PW2						
WRITE ACCES	S	PW2						
MEMORY TYPE	Ξ:	Nonvola	tile (SEE)					
C4h 2 ⁷		2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
_	bit7							bit0
De sitetes te ses								

Register to control DAC1.



Table 02h, Register C5h to C6h: Reserved

FACTORY DEFAULT:	0000 0000h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)

These registers are reserved.

Table 02h, Register C7h: M4 LUT Cntl

FACTORY DEFAULT	00h
READ ACCESS	PW2
WRITE ACCESS	PW2

MEMORY TYPE:

Nonvolatile (SEE)

C7h	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	RESERVED	DBL_SB	UP_LOWB
	bit7							bit0

Controls the size and location of LUT functions for the MON4 measurement.

Bit7:2	RESERVED: Default = 000000b.
	DBL_SB: Chooses the size of LUT for Table 06h.
Bit1	0 = (Default) Single LUT of 32 bytes. 1 = Double LUT of 16 bytes.
	UP_LOWB: Determines which 16-byte LUT is used if DBL_SB = 1. If DBL_SB = 0, the value of this bit is a don't care.
BitO	0 = (Default) Chooses the lower 16 bytes of Table 06h (Registers 80h-8Fh).
	1 = Chooses the upper 16 bytes of Table 06h (Registers 90h-9Fh).

Table 02h, Register C8h to F7h: No Memory

Table 02h, Register F8h to F9h: MAN IBIAS

FACTORY DE	FAULT:	00h			
READ ACCES	S	PW2			
WRITE ACCES	SS	PW2 and ($BIAS-EN = 0$)			
MEMORY TYP	PE:	Volatile			
F8h	RESERVED	RESERVED	2 ¹²		
F9h	27	2 ⁶	2 ⁵		

 RESERVED
 RESERVED
 2¹²
 2¹¹
 2¹⁰
 2⁹
 2⁸
 2⁷

 F9h
 2⁷
 2⁶
 2⁵
 2⁴
 2³
 2²
 2¹
 2⁰

 bit7
 bit0

When BIAS-EN (Table 02h, Register 80h) is written to 0, writes to these bytes will control the IBIAS DAC. See MAN_CNTL (Table 02h, Register FAh) for details.

Table 02h, Register FAh: MAN_CNTL

FACTORY DEFAULT:	00h
READ ACCESS	PW2
WRITE ACCESS	PW2 and (Bias-En = 1)

MEMORY TYPE: Volatile

FAh	RESERVED	MAN_CLK						
	bit7							bit0

When BIAS-EN (Table 02h, Register 80h) is written to zero, bit zero of this byte will control the updates of the MAN IBIAS value to the BIAS output. The values of MAN IBIAS should be written with a separate write command. Setting bit zero to a 1 will clock the MAN IBIAS value to the output DAC for control of IBIAS.

Write the MAN IBIAS value with a write command. 1.

- 2. Set the MAN_CLK bit to a 1 with a separate write command.
- З. Clear the MAN_CLK bit to a 0 with a separate write command.

Table 02h, Register FBh to FCh: BIAS DAC

FACTORY DEFAULT:	00 00h
READ ACCESS	PW2
WRITE ACCESS	N/A

MEMORY TYPE: Nonvolatile (SEE)

FBh	0	0	2 ¹²	2 ¹¹	2 ¹⁰	2 ⁹	2 ⁸	27
FCh	2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

bit7

The digital value indicating the DAC value used for IBIAS output.

Table 02h, Register FDh to FFh: Reserved

FACTORY DEFAULT:	
READ ACCESS	PW2
WRITE ACCESS	N/A

MEMORY TYPE:

FDh	0	0	0	0	0	0	0	0
FEh	0	0	0	0	0	0	0	Х
FFh	Х	Х	Х	Х	Х	Х	Х	Х
	bit7							bit0

These registers are reserved.

Table 03h Register Descriptions

Table 03h, Regis	Table 03h, Register 80h to FFh: PW2 EEPROM							
FACTORY DEFA	JLT	00h						
READ ACCESS		PW2						
WRITE ACCESS		PW2						
MEMORY TYPE:		Nonvolat	tile (EE)					
80h-FFh	EE	EE	EE	EE	EE	EE	EE	EE
	bit7							bit0
PW2 protected E	PW2 protected EEPROM.							

Table 04h Register Descriptions

Table 04h, Register 80h to C7h: MOD LUT

FACTORY DEFAULT	00h						
READ ACCESS	PW2						
WRITE ACCESS	PW2						
MEMORY TYPE:	Nonvolat	ile (EE)					
80h-C7h 2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
bit7							bit0

The digital value for the modulation DAC output.

The Modulation LUT is a set of registers assigned to hold the temperature profile for the modulation DAC. The values in this table combined with the MOD bits in the MOD Ranging register (Table 02h, Register 8Bh) determine the set point for the modulation voltage. The temperature measurement is used to index the LUT (T INDEX, Table 02h, Register 81h) in 2°C increments from -40°C to +102°C, starting at 80h in Table 04h. Register 80h defines the -40°C to -38°C MOD output, register 81h defines -38°C to -36°C MOD output, and so on. Values recalled from this EEPROM memory table are written into the MOD_DAC (Table 02h, Register 82h) location that holds the value until the next temperature conversion. The part can be placed into a manual mode (MOD-EN bit, Table 02h, Register 80h), where MOD_DAC is directly controlled for calibration. If the temperature compensation functionality is not required, then program the entire Table 04h to the desired modulation setting.

Table 05h Register Descriptions

Table 05h, Regis	Table 05h, Register 80h to A3h: APC Tracking Error LUT (APC REF)							
FACTORY DEFAU	JLT	00h						
READ ACCESS		PW2						
WRITE ACCESS		PW2						
MEMORY TYPE:		Nonvolat	ile (EE)					
80h-A3h	27	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2°
	bit7							bit0

The Tracking Error LUT is set of registers assigned to hold the temperature profile for the APC reference DAC. The values in this table combined with the APC bits in the Comp Ranging register (Table 02h, Register 8Dh) determine the set point for the APC loop. The temperature measurement is used to index the LUT (T INDEX, Table 02h, Register 81h) in 4°C increments from -40°C to +100°C, starting at register 80h in Table 05h. Register 80h defines the -40°C to -36°C APC reference value, register 81h defines -36°C to -32°C APC reference value, and so on. Values recalled from this EEPROM memory table are written into the APC DAC (Table 02h, Register 83h) location that holds the value until the next temperature conversion. The part can be placed into a manual mode (APC-EN bit, Table 02h, Register 80h), where APC DAC can be directly controlled for calibration. If tracking error temperature compensation is not required by the application, program the entire LUT to the desired APC set point.

Table 05h, Register A4h to A7h: Reserved

FACTORY DEFAULT:	00h
READ ACCESS	PW2
WRITE ACCESS	PW2
MEMORY TYPE:	Nonvolatile (SEE)
These registers are reserved.	

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Table 06h Register Descriptions

Table 06h, Register 80h to	Table 06h, Register 80h to 9Fh: M4DAC LUT						
FACTORY DEFAULT	00h						
READ ACCESS	PW2						
WRITE ACCESS	PW2						
MEMORY TYPE:	Nonvolat	ile (EE)					
80h-9Fh 2 ⁷	2 ⁶	2 ⁵	2 ⁴	2 ³	2 ²	2 ¹	2 ⁰
bit7							bit0

The M4DAC LUT is set of registers assigned to hold the voltage profile for the M4DAC. The values in this table determine the set point for the M4DAC. The MON4 voltage measurement is used to index the LUT (Vindex, Table 02h, Register 84h), starting at register 80h in Table 06h. Values recalled from this EEPROM memory table are written into the M4DAC (Table 02h, Register 85h) location that holds the value until the next MON4 voltage conversion. The part can be placed into a manual mode (M4DAC-EN bit, Table 02h, Register 80h), where M4DAC is directly controlled for calibration. If voltage compensation is not required by the application, program the entire LUT to the desired M4DAC set point.

Auxiliary Memory A0h Register Descriptions

Auxiliary Memory A0h, Register 00h to 7fh: EEPROM

•	• • •							
FACTORY DEFA	JLT	00h	00h					
READ ACCESS		PW2	PW2					
WRITE ACCESS		PW2	PW2					
MEMORY TYPE:		Nonvolat	Nonvolatile (EE)					
00h-7Fh	EE	EE	EE	EE	EE	EE	EE	EE
	bit7							bit0
EEPROM								

Package Information

For the latest package outline information and land patterns, go to <u>www.maxim-ic.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	DOCUMENT NO.
28 TQFN-EP	T2855+8	<u>21-0140</u>